



Industry-Standard Dual Operational Amplifiers

1 Features

- Wide supply range of 3V to 36V (B, BA versions)
- Quiescent current: 300µA/ch (B, BA versions)
- Unity-gain bandwidth of 1.2MHz (B, BA versions)
- Common-mode input voltage range includes ground, enabling direct sensing near ground
- 2mV input offset voltage maximum at 25°C (BA version)
- 3mV input offset voltage maximum at 25°C (A, B versions)
- Internal RF and EMI filter (B, BA versions)
- On products compliant to MIL-PRF-38535, all parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.

2 Applications

- Merchant network and server power supply units
- Multi-function printers
- Power supplies and mobile chargers
- Motor control: AC induction, brushed DC, brushless DC, high-voltage, low-voltage, permanent magnet, and stepper motor
- Desktop PC and motherboard
- Indoor and outdoor air conditioners
- Washers, dryers, and refrigerators
- AC inverters, string inverters, central inverters, and voltage frequency drives
- Uninterruptible power supplies
- Electronic point-of-sale systems

3 Description

The LM358B and LM2904B devices are the next-generation versions of the industry-standard operational amplifiers (op amps) LM358 and LM2904, which include two high-voltage (36V) op amps. These

devices provide outstanding value for cost-sensitive applications, with features including low offset (300µV, typical), common-mode input range to ground, and high differential input voltage capability.

The LM358B and LM2904B op amps simplify circuit design with enhanced features such as unity-gain stability, lower offset voltage maximum of 3mV (2mV maximum for LM358BA and LM2904BA), and lower quiescent current of 300µA per amplifier (typical). High ESD (2kV, HBM) and integrated EMI and RF filters enable the LM358B and LM2904B devices to be used in the most rugged, environmentally challenging applications.

The LM358B and LM2904B amplifiers are available in micro-sized packaging, such as the SOT23-8, as well as industry standard packages including SOIC, TSSOP, and VSSOP.

Package Information

| PART NUMBER ⁽¹⁾ | PACKAGE | PACKAGE SIZE(2) |
|--|--|-----------------|
| LM358B, LM358BA, LM2904B, LM2904BA, LM358, LM358A, LM2904, LM2904V, LM258, LM258A | _M358, LM358A, D (SOIC 8) 4 9mm x 6mm | |
| LM358B, LM358BA, LM2904B, LM2904BA, LM358, LM358A, LM2904, LM2490V | PW (TSSOP, 8) | 3mm × 6.4mm |
| LM358B, LM358BA, LM2904B, LM2904BA, LM358, LM358A, LM2904, LM2904V, LM258, LM258A | 358B, LM358BA, LM2904B, 2904BA, LM358, LM358A, 2904, LM2904V, LM258, 8) DGK (VSSOP, 8) 3mm × | |
| LM358B, LM358BA, LM2904B, LM2904BA | DDF (SOT-23, 8) | 2.9mm × 2.8mm |
| LM358, LM2904 | PS (SO, 8) | 6.2mm × 7.8mm |
| LM358, LM2904, LM358A, LM258, LM258A | P (PDIP, 8) | 9.81mm × 9.43mm |
| LM158, LM158A | JG (CDIP, 8) | 9.6mm × 6.67mm |
| LM158, LM158A | FK (LCCC, 20) | 8.89mm × 8.89mm |

Family Comparison

| Specification | LM358B LM358BA | LM2904B LM2904BA | LM358 LM358A | LM2904 | LM2904V LM2904AV | LM258 LM258A | LM158 LM158A | Units |
|-----------------------------------|-------------------|---------------------|----------------------|------------|---------------------|---------------------|---------------------|-------|
| Supply voltage | 3 to 36 | 3 to 36 | 3 to 30 | 3 to 26 | 3 to 30 | 3 to 30 | 3 to 30 | V |
| Offset voltage (max, 25°C) | ± 3 ± 2 | ± 3 ± 2 | ± 7 ± 3 | ± 7 | ± 7 ± 2 | ± 5 ± 3 | ± 5 ± 2 | mV |
| Input bias current (typ / max) | 10 / 35 | 10 / 35 | 20 / 250 15 / 100 | 20 / 250 | 20 / 250 | 20 / 150 15 / 80 | 20 / 150 15 / 50 | nA |
| Gain bandwidth product | 1.2 | 1.2 | 0.7 | 0.7 | 0.7 | 0.7 | 0.7 | MHz |
| Supply current (typ, per channel) | 0.3 | 0.3 | 0.35 | 0.35 | 0.35 | 0.35 | 0.35 | mA |
| ESD (HBM) | 2000 | 2000 | 500 | 500 | 500 | 500 | 500 | V |
| Operating ambient temperature | -40 to 85 | -40 to 125 | 0 to 70 | -40 to 125 | -40 to 125 | -25 to 85 | -55 to 125 | °C |

- For all available packages, see the orderable addendum at the end of the data sheet.
- The package size (length × width) is a nominal value and includes pins, where applicable.



Table of Contents

| 1 Features1 | 7 Detailed Description | 25 |
|--|---|-----|
| 2 Applications 1 | 7.1 Overview | |
| 3 Description1 | 7.2 Functional Block Diagram: LM358B, LM358BA, | |
| 4 Pin Configuration and Functions3 | LM2904B, LM2904BA | 25 |
| 5 Specifications4 | 7.3 Feature Description | .26 |
| 5.1 Absolute Maximum Ratings4 | 7.4 Device Functional Modes | .26 |
| 5.2 ESD Ratings 4 | 8 Application and Implementation | 27 |
| 5.3 Recommended Operating Conditions5 | 8.1 Application Information | 27 |
| 5.4 Thermal Information5 | 8.2 Typical Application | 27 |
| 5.5 Electrical Characteristics: LM358B and LM358BA 6 | 8.3 Power Supply Recommendations | 28 |
| 5.6 Electrical Characteristics: LM2904B and | 8.4 Layout | 28 |
| LM2904BA8 | 9 Device and Documentation Support | .30 |
| 5.7 Electrical Characteristics: LM358, LM358A10 | 9.1 Receiving Notification of Documentation Updates | 30 |
| 5.8 Electrical Characteristics: LM2904, LM2904V 11 | 9.2 Support Resources | 30 |
| 5.9 Electrical Characteristics: LM158, LM158A12 | 9.3 Trademarks | 30 |
| 5.10 Electrical Characteristics: LM258, LM258A14 | 9.4 Electrostatic Discharge Caution | 30 |
| 5.11 Typical Characteristics: LM358B and LM2904B 15 | 9.5 Glossary | 30 |
| 5.12 Typical Characteristics: LM158, LM158A, | 10 Revision History | 30 |
| LM258, LM258A, LM358, LM358A, LM2904, and | 11 Mechanical, Packaging, and Orderable | |
| LM2904V22 | Information | 32 |
| 6 Parameter Measurement Information24 | | |
| | | |



4 Pin Configuration and Functions

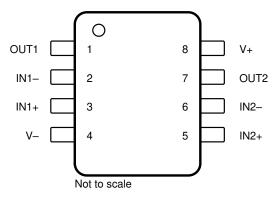
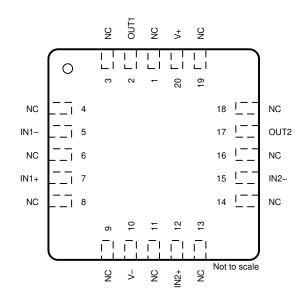


Figure 4-1. D, DDF, DGK, P, PS, PW, and JG
Package
8-Pin SOIC, SOT23-8, VSSOP, PDIP, SO, TSSOP,
and CDIP
Top View



NC - No internal connection

Figure 4-2. FK Package 20-Pin LCCC Top View

Table 4-1. Pin Functions

| | ı | PIN | | |
|------|---|--|-----|--|
| NAME | LCCC ⁽¹⁾ | SOIC, SOT23-8, VSSOP, CDIP, PDIP, SO, TSSOP, CFP ⁽¹⁾ | I/O | DESCRIPTION |
| IN1- | 5 | 2 | I | Negative input |
| IN1+ | 7 | 3 | I | Positive input |
| IN2- | 15 | 6 | I | Negative input |
| IN2+ | 12 | 5 | I | Positive input |
| OUT1 | 2 | 1 | 0 | Output |
| OUT2 | 17 | 7 | 0 | Output |
| V- | 10 | 4 | _ | Negative (lowest) supply or ground (for single-supply operation) |
| NC | 1, 3, 4, 6, 8, 9, 11, 13, 14, 16, 18, 19 | _ | _ | No internal connection |
| V+ | 20 | 8 | _ | Positive (highest) supply |

⁽¹⁾ For a listing of which devices are available in what packages, see Section 3.



5 Specifications

5.1 Absolute Maximum Ratings

over operating ambient temperature range (unless otherwise noted)(1)

| | | | MIN | MAX | UNIT |
|--|---------------------------|--|-------------|-----------|------|
| | | LM358B, LM358BA, LM2904B, LM2904BA | | ±20 or 40 | |
| Supply voltage, $V_S = ([V+] - [V-])$ | | LM158, LM258, LM358, LM158A, LM258A, LM358A, LM2904V | | ±16 or 32 | V |
| | | LM2904 | | ±13 or 26 | |
| Differential input voltage, V _{ID} ⁽²⁾ | | LM358B, LM358BA, LM2904B, LM2904BA,LM158, LM258, LM358, LM158A, LM258A, LM358A, LM2904V | -32 | 32 | V |
| | | LM2904 | -26 | 26 | |
| | | LM358B, LM358BA, LM2904B, LM2904BA | -0.3 | 40 | |
| Input voltage, V _I | Either input | LM158, LM258, LM358, LM158A, LM258A, LM358A, LM2904V | -0.3 | 32 | V |
| | | LM2904 | -0.3 | 26 | |
| Duration of output short circuit (one amp $V_S \le 15 V^{(3)}$ | olifier) to ground at (or | below) T _A = 25°C, | | Unlimited | s |
| | | LM158, LM158A | - 55 | 125 | |
| | | LM258, LM258A | -25 | 85 | |
| Operating ambient temperature, T _A | | LM358B, LM358BA | -40 | 85 | °C |
| operating annalon temperature, 14 | | LM358, LM358A | 0 | 70 | |
| | | LM2904B, LM2904BA, LM2904, LM2904V | -40 | 125 | |
| Operating virtual-junction temperature, | T _J | | | 150 | °C |
| Storage temperature, T _{stg} | | | -65 | 150 | °C |

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 ESD Ratings

| | | | VALUE | UNIT | |
|--------------------|-------------------------|--|-------|------|--|
| LM358E | B, LM358BA, LM2904B, A | ND LM2904BA | | | |
| V | Clastrostatia diasharas | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | ±2000 | | |
| V _(ESD) | Electrostatic discharge | Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾ | | , v | |
| LM158, | LM258, LM358, LM158, L | M258A, LM358A, LM2904, AND LM2904V | | | |
| V | Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | ±500 | \/ | |
| V _(ESD) | Liectiostatic discharge | Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾ | ±1000 | v | |

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

⁽²⁾ Differential voltages are at IN+, with respect to IN-.

⁽³⁾ Short circuits from outputs to V_S can cause excessive heating and eventual destruction.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



5.3 Recommended Operating Conditions

over operating ambient temperature range (unless otherwise noted)

| | | | MIN | MAX | UNIT |
|-----------------|--|---|-----|--------|------|
| | Supply voltage, V _S = ([V+] – [V–]) | LM358B, LM358BA, LM2904B, LM2904BA | 3 | 36 | |
| Vs | | LM158, LM258, LM358, LM158A, LM258A, LM358A, LM2904V | 3 | 30 | V |
| | | LM2904 | 3 | 26 | |
| V _{CM} | Common-mode voltage | | V- | V+ - 2 | V |
| | | LM358B, LM358BA | -40 | 85 | |
| _ | | LM2904B, LM2904BA, LM2904, LM2904V | -40 | 125 | |
| T _A | Operating ambient temperature | LM358, LM358A | 0 | 70 | °C |
| | | LM258, LM258A | -20 | 85 | |
| | | LM158, LM158A | -55 | 125 | |

5.4 Thermal Information

| | | LM258, LM | M258, LM258A, LM358, LM358A, LM358B, LM358BA, LM2904, LM2904B, LM2904BA, LM2904V ⁽²⁾ | | | | LM158, | | | |
|-----------------------|--|-----------|---|-------------|------------|---------------|-----------------|--------------|--------------|------|
| Т | THERMAL METRIC ⁽¹⁾ | | DGK (VSSOP) | P (PDIP) | PS (SO) | PW (TSSOP) | DDF (SOT-23) | FK (LCCC) | JG (CDIP) | UNIT |
| | | 8 PINS | 8 PINS | 8 PINS | 8 PINS | 8 PINS | 8PINS | 20 PINS | 8 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 124.7 | 181.4 | 80.9 | 116.9 | 171.7 | 164.3 | 84.0 | 112.4 | °C/W |
| R _{θJC(top)} | Junction-to-case (top) thermal resistance | 66.9 | 69.4 | 70.4 | 62.5 | 68.8 | 98.1 | 56.9 | 63.6 | °C/W |
| R _{θJB} | Junction-to-board thermal resistance | 67.9 | 102.9 | 57.4 | 68.6 | 99.2 | 82.1 | 57.5 | 100.3 | °C/W |
| ΨЈТ | Junction-to-top characterization parameter | 19.2 | 11.8 | 40 | 21.9 | 11.5 | 11.4 | 51.7 | 35.7 | °C/W |
| ΨЈВ | Junction-to-board characterization parameter | 67.2 | 101.2 | 56.9 | 67.6 | 97.9 | 81.7 | 57.1 | 93.3 | °C/W |
| R _{θJC(bot)} | Junction-to-case (bottom) thermal resistance | _ | _ | _ | _ | _ | _ | 10.6 | 22.3 | °C/W |

⁽¹⁾ For more information about traditional and new thermal metrics, see Semiconductor and IC Package Thermal Metrics.

⁽²⁾ For a listing of which devices are available in what packages, see Section 3.



5.5 Electrical Characteristics: LM358B and LM358BA

 $V_S = (V+) - (V-) = 5 V - 36 V (\pm 2.5 V - \pm 18 V), T_A = 25^{\circ}C, V_{CM} = V_{OUT} = V_S / 2, R_L = 10k connected to <math>V_S / 2$ (unless otherwise noted)

| (uniess | otherwise noted) | | | | | | | |
|----------------------------------|---|---|--|---|------|-----------|------------|--------------|
| | PARAMETER | | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
| OFFSET | VOLTAGE | | | | | | | |
| | | LM358B | | | | ±0.3 | ±3.0 | mV |
| Vos | Input offset voltage | | | $T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$ | | | ±4 | mV |
| •03 | Input once voltage | LM358BA | | | | | ±2.0 | mV |
| | | LWOSOBA | | $T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$ | | | ±2.5 | mV |
| dV_{OS}/d_{T} | Input offset voltage drift | | | $T_A = -40^{\circ}C \text{ to } +85^{\circ}C^{(1)}$ | | ±3.5 | 11 | μV/°C |
| PSRR | Power supply rejection ratio | | | • | | ±2 | 15 | μV/V |
| | Channel separation, dc | f = 1 kHz to 20 kHz | | | | ±1 | | μV/V |
| INPUT V | OLTAGE RANGE | | | | | | | |
| | | V _S = 3 V to 36 V | | | (V-) | | (V+) - 1.5 | V |
| V _{CM} | Common-mode voltage range | V _S = 5 V to 36 V | | T _A = -40°C to +85°C | (V-) | | (V+) – 2 | V |
| | | $(V-) \le V_{CM} \le (V+) - 1.5 \text{ V}$ | V _S = 3 V to 36 V | | | 20 | 100 | |
| CMRR | Common-mode rejection ratio | $(V-) \le V_{CM} \le (V+) - 2.0 \text{ V}$ | | T _A = -40°C to +85°C | | 25 | 316 | μV/V |
| INPUT B | AS CURRENT | (* / = * GM = (* / = = * * | 1.3 | 1 A 10 C 11 C C | | | | |
| | | | | | | -10 | -35 | nA |
| I_B | Input bias current | | | $T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}^{(1)}$ | | | -50 | nA |
| | | | | 1A40 C to +65 C | | 0.5 | | |
| Ios | Input offset current | | | T = 40%C t= :05%C(1) | | 0.5 | 4 | nA |
| | | | | $T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}^{(1)}$ | | | 5 | nA |
| dl _{OS} /d _T | Input offset current drift | | | $T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$ | | 10 | | pA/°C |
| NOISE | I | | | | | | | |
| En | Input voltage noise | f = 0.1 to 10 Hz | | | | 3 | | μV_{PP} |
| e _n | Input voltage noise density | f = 1 kHz | | | | 40 | | nV/√/Hz |
| INPUT IN | IPEDANCE | | | | | | | |
| Z_{ID} | Differential | | | | | 10 0.1 | | MΩ pF |
| Z _{IC} | Common-mode | | | | | 4 1.5 | | GΩ pF |
| OPEN-LO | OOP GAIN | | | | | | | |
| | 0 | V 45 V V 4 V 4 44 V | (D > 40 b0 | | 70 | 140 | | V/mV |
| A _{OL} | Open-loop voltage gain | $V_S = 15 \text{ V}; V_O = 1 \text{ V to } 11 \text{ V}$ | V; R _L ≥ 10 kΩ, connected to (V–) | T _A = -40°C to +85°C | 35 | | | V/mV |
| FREQUE | NCY RESPONSE | | | | | | | |
| GBW | Gain bandwidth product | | | | | 1.2 | | MHz |
| SR | Slew rate | G = + 1 | | | | 0.5 | | V/µs |
| Θ _m | Phase margin | $G = + 1$, $R_L = 10k\Omega$, $C_L = 2$ | 20 pF | | | 56 | | • |
| t _{OR} | Overload recovery time | V _{IN} × gain > V _S | F: | | | 10 | | μs |
| t _s | Settling time | To 0.1%, V _S = 5 V, 2-V ste | n G = +1 C = 100 pF | | | 4 | | μs |
| THD+N | Total harmonic distortion + noise | | 53 V _{RMS} , V _S = 36 V, R _L = 100k, I _{OUT} ≤ ±50 | μΛ RW = 80 kHz | | 0.001 | | |
| OUTPUT | Total Harmonic distortion + Hoise | G = + 1,1 = 1 KHZ, V ₀ = 3. | 33 VRMS, VS = 30 V, IVL = 100K, IOUT = 130 | μΑ, Βνν – ου κι ιΖ | | | | 70 |
| OUIFUI | | | | 1 - 50 | | 4.05 | 4.40 | V |
| | | Desition will (1/1) | | Ι _{ΟUT} = 50 μΑ | | 1.35 | 1.42 | |
| | | Positive rail (V+) | | I _{OUT} = 1 mA | | 1.4 | 1.48 | V |
| Vo | Voltage output swing from rail | | | I _{OUT} = 5 mA ⁽¹⁾ | | 1.5 | 1.61 | V |
| | | | | I _{OUT} = 50 μA | | 100 | 150 | mV |
| | | Negative rail (V-) | | I _{OUT} = 1 mA | | 0.75 | 1 | V |
| | | | V _S = 5 V, RL ≤ 10 kΩ connected to (V–) | $T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$ | | 5 | 20 | mV |
| | | V _S = 15 V; V _O = V-; V _{ID} = 1 V | Source ⁽¹⁾ | | -20 | -30 | | |
| | | V _{ID} = 1 V | | $T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$ | -10 | | | mA |
| Io | Output current | V _S = 15 V; V _O = V+; V _{ID} = -1 V | Sink ⁽¹⁾ | | 10 | 20 | | 111/1 |
| | V _{ID} = -1 V | $T_A = -40^{\circ}\text{C to } + 8$ | | 5 | | | | |
| | | V _{ID} = -1 V; V _O = (V-) + 20 | 0 mV | | 60 | 100 | | μΑ |
| I _{SC} | Short-circuit current | V _S = 20 V, (V+) = 10 V, (V- | -) = -10 V, V _O = 0 V | | | ±40 | ±60 | mA |
| C _{LOAD} | Capacitive load drive | | | | | 100 | | pF |
| R _O | Open-loop output resistance | f = 1 MHz, I _O = 0 A | | | | 300 | | Ω |
| | <u>, , , , , , , , , , , , , , , , , , , </u> | 1 3 5 | | | | | | |

SLOS068AB - JUNE 1976 - REVISED OCTOBER 2024

5.5 Electrical Characteristics: LM358B and LM358BA (continued)

 V_S = (V+) - (V-) = 5 V - 36 V (±2.5 V - ±18 V), T_A = 25°C, V_{CM} = V_{OUT} = V_S / 2, R_L = 10k connected to V_S / 2 (unless otherwise noted)

| PARAMETER TEST | | TEST CONDITIONS | ST CONDITIONS | | TYP | MAX | UNIT |
|----------------|---------------------------------|---|---------------------------------|--|-----|-----|------|
| POWER | POWER SUPPLY | | | | | | |
| IQ | Quiescent current per amplifier | V _S = 5 V; I _O = 0 A | T _A = -40°C to +85°C | | 300 | 460 | μA |
| IQ | Quiescent current per amplifier | V _S = 36 V; I _O = 0 A | | | | 800 | μΑ |

(1) Specified by characterization only.

5.6 Electrical Characteristics: LM2904B and LM2904BA

 $V_S = (V+) - (V-) = 5 \text{ V} - 36 \text{ V} (\pm 2.5 \text{ V} - \pm 18 \text{ V}), T_A = 25^{\circ}\text{C}, V_{CM} = V_{OUT} = V_S/2, R_L = 10 \text{k connected to } V_S/2$

| (di iies | s otherwise noted) | | TEOT COMPLETE | | | F 1/2 | | 1 |
|----------------------------------|---|---|---|--|------|--------------|------------|------------------|
| | PARAMETER | | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
| OFFSET | VOLTAGE | T | | I | r | | | |
| | | LM2904B | | | | ±0.3 | ±3.0 | mV |
| Vos | Input offset voltage | 211120013 | | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | | ±4 | mV |
| VOS | input onset voltage | LM2904BA | | | | | ±2.0 | mV |
| | | LIVIZ304DA | | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | | ±3.0 | mV |
| dV _{OS} /d _T | Input offset voltage drift | | | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}^{(1)}$ | | ±3.5 | 12 | μV/°C |
| PSRR | Power Supply Rejection Ratio | | | • | | ±2 | 15 | μV/V |
| | Channel separation, dc | f = 1 kHz to 20 kHz | | | | ±1 | | μV/V |
| INPUT V | OLTAGE RANGE | | | | | | | |
| ., | | V _S = 3 V to 36 V | | | (V-) | | (V+) – 1.5 | ٧ |
| V _{CM} | Common-mode voltage range | V _S = 5 V to 36 V | | T _A = -40°C to +125°C | (V-) | | (V+) – 2 | V |
| | | $(V-) \le V_{CM} \le (V+) - 1.5 \text{ V}$ | V _S = 3 V to 36 V | | | 20 | 100 | |
| CMRR | Common-mode rejection ratio | $(V-) \le V_{CM} \le (V+) - 2.0 \text{ V}$ | V _S = 5 V to 36 V | T _A = -40°C to +125°C | | 25 | 316 | μV/V |
| INPUT B | IAS CURRENT | | - | | | | | |
| | Input higo ourrant | | | | | -10 | -35 | nA |
| I _B | Input bias current | | | $T_A = -40$ °C to +125°C ⁽¹⁾ | | | -50 | nA |
| | land offer to the state of the | | | | | 0.5 | 4 | nA |
| los | Input offset current | | | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}^{(1)}$ | | | 5 | nA |
| dl _{OS} /d _T | Input offset current drift | | | T _A = -40°C to +125°C | | 10 | | pA/°C |
| NOISE | 1 | | | 1 | | | | l |
| En | Input voltage noise | f = 0.1 to 10 Hz | | | | 3 | | μV _{PP} |
| e _n | Input voltage noise density | f = 1 kHz | | | | 40 | | nV/√/Hz |
| | // PEDANCE | | | | | | | |
| Z _{ID} | Differential | | | | 1 | 10 0.1 | | MΩ pF |
| Z _{IC} | Common-mode | | | | | 4 1.5 | | GΩ pF |
| | OOP GAIN | | | | | | | - 111 |
| <u> </u> | | | | | 70 | 140 | | V/mV |
| A _{OL} | Open-loop voltage gain | V _S = 15 V; V _O = 1 V to 11 V | V; R _L ≥ 10 kΩ, connected to (V-) | T _A = -40°C to +125°C | 35 | 140 | | V/mV |
| FREQUE | NCY RESPONSE | | | 1A 40 0 to 1120 0 | - 00 | | | V/111V |
| GBW | Gain bandwidth product | | | | | 1.2 | | MHz |
| SR | Slew rate | G = + 1 | | | | 0.5 | | V/µs |
| | Phase margin | $G = +1, R_L = 10k\Omega, C_L = 2$ | 20 pE | | | 56 | | ν/μ5 |
| Θ _m | <u> </u> | | и рг | | | | | |
| t _{OR} | Overload recovery time | V _{IN} × gain > V _S | . 0 .4.0 .400 | | | 10 | | μs |
| t _s | Settling time | To 0.1%, $V_S = 5 \text{ V}$, 2-V Ste | · · · · · · · · · · · · · · · · · · · | A DW 00111 | | 4 | | μs |
| THD+N | Total harmonic distortion + noise | $G = +1, f = 1 \text{ KHz}, V_0 = 3.$ | $53 \text{ V}_{RMS}, \text{ V}_{S} = 36 \text{ V}, \text{ R}_{L} = 100 \text{ k}, \text{ I}_{OUT} \le \pm 50 \text{ J}_{OUT}$ | JA, BW = 80 KHZ | | 0.001 | | % |
| OUTPUT | · | <u> </u> | | T | | | | |
| | | | | Ι _{ΟUT} = 50 μΑ | | 1.35 | 1.42 | V |
| | | Positive Rail (V+) | | I _{OUT} = 1 mA | | 1.4 | 1.48 | V |
| Vo | Voltage output swing from rail | | T | I _{OUT} = 5 mA ⁽¹⁾ | | 1.5 | 1.61 | V |
| - | | | | Ι _{ΟUT} = 50 μΑ | | 100 | 150 | mV |
| | | Negative Rail (V-) | | I _{OUT} = 1 mA | | 0.75 | 1 | V |
| | | | V _S = 5 V, RL ≤ 10 kΩ connected to (V–) | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | 5 | 20 | mV |
| | | V _S = 15 V; V _O = V-; V _{ID} = 1 V | Source ⁽¹⁾ | | -20 | -30 | | |
| | | 1 V | | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | -10 | | | mA |
| Io | Output current | V _S = 15 V; V _O = V+; V _{ID} = | Sink ⁽¹⁾ | | 10 | 20 | | |
| | | -1 V | | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | 5 | | | |
| | | V _{ID} = -1 V; V _O = (V-) + 200 | mV | | 60 | 100 | | μA |
| I _{SC} | Short-circuit current | V _S = 20 V, (V+) = 10 V, (V- |) = -10 V, V _O = 0 V | | | ±40 | ±60 | mA |
| C _{LOAD} | Capacitive load drive | | | | | 100 | | pF |
| R _O | Open-loop output resistance | f = 1 MHz, I _O = 0 A | | | | 300 | | Ω |
| | SUPPLY | 1 | | | I | | | 1 |



www.ti.com

 V_S = (V+) - (V-) = 5 V - 36 V (±2.5 V - ±18 V), T_A = 25°C, V_{CM} = V_{OUT} = $V_S/2$, R_L = 10k connected to $V_S/2$ (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|----|---------------------------------|---|--|-----|-----|-----|------|
| IQ | Quiescent current per amplifier | $V_S = 5 V; I_O = 0 A$ | T. = 40°C to ±125°C | | 300 | 460 | μΑ |
| ΙQ | Quiescent current per amplifier | V _S = 36 V; I _O = 0 A | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$ | | | 800 | μΑ |

(1) Specified by characterization only

5.7 Electrical Characteristics: LM358, LM358A

| | $= (V+) - (V-) = 5 V, T_A$ PARAMETER | | TEST CONE | | | MIN | TYP ⁽²⁾ | MAX | UNIT | |
|-----------------------------------|---|---|---|----------------------|------------------------------|------|--------------------|------------|--------------------|--|
| OFFSET \ | /OLTAGE | | | | | | | | | |
| | | | | | | | 3 | 7 | | |
| | | V = 5 V to 20 V V | 01/11/ - 1.1 | LM358 | T _A = 0°C to 70°C | | <u> </u> | 9 | | |
| Vos | Input offset voltage | $V_S = 5 \text{ V to } 30 \text{ V; } V_{C \text{ M}} = 0$ | 0 v; v _O = 1.4 | LM358A | 1A 0 0 10 10 0 | | 2 | 3 | mV | |
| | | | | LIVIOUGIA | T _A = 0°C to 70°C | | | 5 | | |
| | | | | LM358 | | | 7 | 3 | | |
| dV_{OS}/d_T | Input offset voltage drift | | | | T _A = 0°C to 70°C | | 7 | 20 | μV/°C | |
| | | | | LM358A | T _A = 0°C to 70°C | | 1 | 20 | | |
| PSRR | Input offset voltage vs power supply $(\Delta V_{IO}/\Delta V_S)$ | V _S = 5 V to 30 V | | | | 65 | 100 | | dB | |
| V _{O1} / V _{O2} | Channel separation | f = 1 kHz to 20 kHz | | | | | 120 | | dB | |
| | LTAGE RANGE | | | | | | | | | |
| | | V _S = 5 V to 30 V | | LM358 | | | | | | |
| | | V _S = 30 V | | LM358A | | (V–) | | (V+) – 1.5 | | |
| V_{CM} | Common-mode voltage range | V _S = 5 V to 30 V | | LM358 | | | | | V | |
| | | V _S = 30 V | | LM358A | T _A = 0°C to 70°C | (V–) | | (V+) – 2 | | |
| CMRR | Common-mode rejection ratio | V _S = 5 V to 30 V; V _{CM} = 0 |) V | LIVIOUGIA | | 65 | 80 | | dB | |
| | AS CURRENT | TAS OF TO GO V, VCM | | | | | | | ub ub | |
| 1111 01 01 | -O OURILINI | | | | | | -20 | -250 | | |
| | | | | LM358 | T = 0°C to 70°C | | -20 | -500 | | |
| IB | Input bias current | V _O = 1.4 V | | | T _A = 0°C to 70°C | | 45 | | nA | |
| | | | | LM358A | T 000 to 7000 | | –15 | -100 | | |
| | | | | | T _A = 0°C to 70°C | | | -200 | | |
| | | | | LM358 | | | 2 | 50 | | |
| Ios | Input offset current | V _O = 1.4 V | | | T _A = 0°C to 70°C | | | 150 | nA | |
| | | | | LM358A | | | 2 | 30 | | |
| | | | | | T _A = 0°C to 70°C | | | 75 | | |
| dl _{OS} /d _T | Input offset current drift | | | | | | 10 | | pA/°C | |
| | | | | LM358A | T _A = 0°C to 70°C | | | 300 | | |
| NOISE | | | | | | | | | | |
| e _n | Input voltage noise density | f = 1 kHz | | | | | 40 | | nV/√ Hz | |
| OPEN-LO | OP GAIN | | | | | | | | | |
| A _{OL} | Open-loop voltage gain | V _S = 15 V; V _O = 1 V to 11 | V: R. > 2 k∩ | | | 25 | 100 | | V/mV | |
| , (OL | | 15 10 1, 10 1 1 10 11 | V, I'L = 2 K32 | | T _A = 0°C to 70°C | 15 | | | V/111V | |
| FREQUEN | NCY RESPONSE | | | | | | | | | |
| GBW | Gain bandwidth product | | | | | | 0.7 | | MHz | |
| SR | Slew rate | G = +1 | | | | | 0.3 | | V/µs | |
| OUTPUT | | | | | | | | , | | |
| | | | V _S = 30 V; R | L = 2 kΩ | T _A = 0°C to 70°C | | | 4 | | |
| | | Positive rail | V _S = 30 V; R | _L ≥ 10 kΩ | | | 2 | 3 | V | |
| Vo | Voltage output swing from rail | | V _S = 5 V; R _L | ≥ 2 kΩ | | | | 1.5 | | |
| | | Negative rail | V _S = 5 V; R _I | | T _A = 0°C to 70°C | | 5 | 20 | mV | |
| | | - | | | 1 | -20 | -30 | | | |
| | | V _S = 15 V; V _O = 0 V; V _{ID} = 1 V | Source | LM358A | | | | -60 | | |
| | | = 1 V | | | T _A = 0°C to 70°C | -10 | | | mA | |
| Io | Output current | V = 45 V V 45 V | | 1 | n | 10 | 20 | | | |
| | | $V_S = 15 \text{ V}; V_O = 15 \text{ V}; V_{ID} = -1 \text{ V}$ | Sink | | T _A = 0°C to 70°C | 5 | 20 | | | |
| | | | <u> </u> | | 1A - 0 0 to 10 0 | 12 | 30 | | μA | |
| laa | Short-circuit current | $V_{S} = 10 \text{ V}; V_{O} = V_{S} / 2$ | V _{ID} = -1 V; V _O = 200 mV | | | | | ±60 | mA | |
| POWER S | | v _S - 10 v, v _O = v _S /2 | | | | | ±40 | 100 | IIIA | |
| FUWER S | DUFFLI | V = 2.5.V. 1 | | | | | 050 | 000 | | |
| IQ | Quiescent current per amplifier | V _O = 2.5 V; I _O = 0 A | 0.4 | | T _A = 0°C to 70°C | | 350 | 600 | μΑ | |
| | | V _S = 30 V; V _O = 15 V; I _O | = 0 A | | | | 500 | 1000 | | |

⁽¹⁾ All characteristics are measured under open-loop conditions, with zero common-mode input voltage, unless otherwise specified. Maximum V_S for testing purposes is 30 V for LM358 and LM358A.

⁽²⁾ All typical values are T_A = 25°C.



5.8 Electrical Characteristics: LM2904, LM2904V

| | PARAMETER | | TES | ST COND | ITIONS ⁽¹⁾ | | MIN | TYP (2) | MAX | UNIT |
|-----------------------------------|---|--|---------------------------------|-------------------------|---------------------------|---|----------------------|---------|------------|--------------------|
| OFFSET | VOLTAGE | | | | | | | | | |
| | | | | | | | | 3 | 7 | |
| | | | | | Non-A suffix devices | T = 40°C to 405°C | | | 10 | |
| Vos | Input offset voltage | V _S = 5 V to max | imum; $V_{CM} = 0 V$; | V _O = | 4011000 | T _A = -40°C to 125°C | | | | mV |
| | | 1.4 V | | | A-suffix | | | 1 | 2 | |
| | | | | | devices | $T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$ | | | 4 | |
| dV _{OS} /d _T | Input offset voltage drift | | | | | $T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$ | | 7 | | μV/°C |
| PSRR | Input offset voltage vs power supply $(\Delta V_{IO}/\Delta V_S)$ | V _S = 5 V to 30 V | r | | | | 65 | 100 | | dB |
| V _{O1} / V _{O2} | Channel separation | f = 1 kHz to 20 k | Hz | | | | | 120 | | dB |
| INPUT V | OLTAGE RANGE | | | | | | | | | |
| | | | | | | | (V-) | | (V+) - 1.5 | |
| V _{CM} | Common-mode voltage range | V _S = 5 V to max | imum | | | T _A = -40°C to 125°C | (V-) | | (V+) – 2 | V |
| CMRR | Common-mode rejection ratio | Vo = 5 V to max | imum; V _{CM} = 0 V | | | A | 65 | 80 | , , | dB |
| | IAS CURRENT | VS = 5 V to max | imam, v _{CM} = 0 v | | | | 03 | | | ub ub |
| MPUIB | IAS CURRENT | 1 | | | | | | | | |
| I _B | Input bias current | V _O = 1.4 V | | | | | | -20 | -250 | nA |
| | | | | | | $T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$ | | | -500 | |
| | | | | | Non-V suffix | | | 2 | 50 | |
| | Input offset current | V = 1.4.V | | | device | $T_A = -40^{\circ}C \text{ to } 125^{\circ}C$ | | | 300 | nA |
| los | input onset current | V _O = 1.4 V | V-suffix | | | | 2 | 50 | IIA | |
| | | | | | device | T _A = -40°C to 125°C | | | 150 | |
| dl _{OS} /d _T | os/d _T Input offset current drift | | | | | | | 10 | | pA/°C |
| NOISE | <u> </u> | | | | | $T_A = -40^{\circ}C \text{ to } 125^{\circ}C$ | | | | |
| | Input voltage noise density | f = 1 kHz | | | | | | 40 | | nV/√ Hz |
| e _n | | I - I KIIZ | | | | | | 40 | | 110/1112 |
| OPEN-LO | DOP GAIN | 1 | | | | 1 | | | | |
| A _{OL} | Open-loop voltage gain | V _S = 15 V: V _O = | 1 V to 11 V; R _L ≥ 2 | 2 kΩ | | | 25 | 100 | | V/mV |
| | | | | | | $T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$ | 15 | | | |
| FREQUE | NCY RESPONSE | | | | | | | | | |
| GBW | Gain bandwidth product | | | | | | | 0.7 | | MHz |
| SR | Slew rate | G = +1 | | | | | | 0.3 | | V/µs |
| OUTPUT | | | | | | | | - | | |
| | | | R _L ≥ 10 kΩ | | | | V _S – 1.5 | | | |
| | | | 1.5 | V ma | ximum; R _L = | | 13 | | | |
| | | | Non-V suffix | 2 kΩ | ixiiiiuiii, i\[- | | | | 4 | |
| | | | device | V _s = ma | ıximum; R _I ≥ | | | | | |
| ., | Voltage cutmut cuing from well | Positive rail | | 10 kΩ | , - | T = 40°C to 405°C | | 2 | 3 | V |
| Vo | Voltage output swing from rail | | | | ximum; R _L = | $T_A = -40$ °C to 125°C | | | 6 | |
| | | | V-suffix device | 2 kΩ | | | | | 0 | |
| | | | | | ximum; R _L ≥ | | | 4 | 5 | |
| | | | | 10 kΩ | | | | | | |
| | | Negative rail | | V _S = 5 V | /; R _L ≤ 10 kΩ | T _A = -40°C to 125°C | | 5 | 20 | mV |
| | | V _S = 15 V; V _O = | 0 V: V = 1 V | Source | | | -20 | -30 | | |
| | | 'S - 15 v, v ₀ - | ∪ v, v _{ID} – i v | Cource | | T _A = -40°C to 125°C | -10 | | | m A |
| | | | | a | | | 10 | 20 | | mA |
| l _o | Output current | $V_S = 15 \text{ V}; V_O =$ | 15 V; V _{ID} = -1 V | Sink | | T _A = -40°C to 125°C | 5 | | | |
| | | | | Non-V s | uffix device | | | 30 | | |
| | | V _{ID} = -1 V; V _O = | 200 mV | V-suffix | | | 12 | 40 | | μΑ |
| | Ob and almostid account | 14 463434 | N. 10 | v-suiliX | uc vice | | 14 | | . 0.5 | |
| I _{SC} | Short-circuit current | V _S = 10 V; V _O = | V _S / 2 | | | | | ±40 | ±60 | mA |
| POWER | SUPPLY | | | | | | | | ı | |
| lo. | Quiescent current per amplifier | V _O = 2.5 V; I _O = | 0 A | | | T _A = -40°C to 125°C | | 350 | 600 | μA |
| IQ | and soon canonit per amplified | V _S = maximum; | V _O = maximum / 2 | 2; I _O = 0 A | | 1A = ===0 0 t0 123 0 | | 500 | 1000 | μΛ |
| | | | J | , 571 | | | | | .000 | |

⁽¹⁾ All characteristics are measured under open-loop conditions, with zero common-mode input voltage, unless otherwise specified. Maximum V_S for testing purposes is 26 V for LM2904 and 32 V for LM2904V.

⁽²⁾ All typical values are $T_A = 25$ °C.

5.9 Electrical Characteristics: LM158, LM158A

| | PARAMETER | TE | ST CONDI | TIONS ⁽¹⁾ | | MIN | TYP ⁽²⁾ | MAX | UNIT |
|-----------------------------------|---|---|-----------------------|---|---|------|--------------------|-------------------|--------------------|
| OFFSET | VOLTAGE | | | | | | | | |
| | | | | LM158 | | | 3 | 5 | |
| , | Input offset voltage | V _S = 5 V to 30 V; V _{C M} = 0 V; V _C | -141/ | LIVITO | T _A = -55°C to 125°C | · | | 7 | m\/ |
| Vos | input onset voltage | VS - 5 V 10 50 V, VC M - 0 V, VC |) - 1.4 V | 1.84450.4 | | , | | 2 | mV |
| | | | | LM158A | T _A = -55°C to 125°C | | | 4 | |
| | | | | LM158 | T _A = -55°C to 125°C | , | 7 | | |
| dV _{OS} /d _T | Input offset voltage drift | | | LM158A | T _A = -55°C to 125°C | | 7 | 15 ⁽³⁾ | μV/°C |
| PSRR | Input offset voltage vs power supply $(\Delta V_{IO}/\Delta V_S)$ | V _S = 5 V to 30 V | | | | 65 | 100 | | dB |
| V ₀₁ / V ₀₂ | Channel separation | f = 1 kHz to 20 kHz | | | | | 120 | | dB |
| NPUT V | OLTAGE RANGE | | | | | | - | | |
| | | V _S = 5 V to 30 V | | LM158 | | | | | |
| | | V _S = 30 V | | LM158A | | (V-) | | (V+) – 1.5 | |
| V _{CM} | Common-mode voltage range | V _S = 5 V to 30 V | | LM158 | | | | | V |
| | | V _S = 30 V | | LM158A | $T_A = -55^{\circ}\text{C to } 125^{\circ}\text{C}$ | (V-) | | (V+) – 2 | |
| CMRR | Common-mode rejection ratio | V _S = 5 V to 30 V; V _{CM} = 0 V | | | | 70 | 80 | | dB |
| | AS CURRENT | 15 0 1 to 00 1, TCM 0 1 | | | | | | | 45 |
| 51 61 | | | | 1 | | | -20 | -150 | |
| | | | | LM158 | T _A = -55°C to 125°C | | -20 | -300 | |
| В | Input bias current | V _O = 1.4 V | | 1A = -55 C to 125 C | | -15 | -50 -50 | nA | |
| | | | | LM158A | T _A = -55°C to 125°C | | -15 | | |
| | | | | | 1 _A = -55 C to 125 C | | | -100 | |
| | | | | LM158 | | | 2 | 30 | |
| os | Input offset current | V _O = 1.4 V | | | T _A = -55°C to 125°C | | | 100 | nA |
| | | | | LM158A | | | 2 | 10 | |
| | | | | | T _A = -55°C to 125°C | | | 30 | |
| dl _{OS} /d _T | Input offset current drift | | | | | | 10 | | pA/°C |
| 031 | | | | LM158A | T _A = -55°C to 125°C | | | 200 | p |
| NOISE | | | | | | | | | |
| e _n | Input voltage noise density | f = 1 kHz | | | | | 40 | | nV/√ Hz |
| OPEN-LO | OOP GAIN | | | | | | | | |
| | O I | V 45.V.V 4.V.E 44.V.D | > 0 t-0 | | | 50 | 100 | | \ //\ / |
| A _{OL} | Open-loop voltage gain | $V_S = 15 \text{ V}; V_O = 1 \text{ V to } 11 \text{ V}; R_L$ | ≥ 2 KΩ | | T _A = -55°C to 125°C | 25 | | | V/mV |
| FREQUE | NCY RESPONSE | | | | | , | 1 | | |
| GBW | Gain bandwidth product | | | | | | 0.7 | | MHz |
| SR | Slew rate | G = +1 | | | | | 0.3 | | V/µs |
| OUTPUT | | | | | | | | | |
| | | | V _S = 30 V | '; R _L = 2 kΩ | T _A = -55°C to 125°C | | | 4 | |
| | | Positive rail | | ; R _L ≥ 10 kΩ | A | | 2 | 3 | V |
| √o | Voltage output swing from rail | | | R _L ≥ 2 kΩ | | , | | 1.5 | |
| | | Negative rail | | $R_{l} \le 10 \text{ k}\Omega$ | T _A = -55°C to 125°C | | 5 | 20 | mV |
| | | 14cgative rail | VS - 3 V, | T(_ = 10 K22 | 1A = -00 0 to 120 0 | -20 | -30 | 20 | 1110 |
| | | \\ -15\\\\\ -0\\\\\\\\\ | Course | 1 M150A | | -20 | | 60 | |
| | | $V_S = 15 \text{ V}; V_O = 0 \text{ V}; V_{ID} = 1 \text{ V}$ | Source | LM158A | T - 55°C + 405°C | 40 | | -60 | A |
| lo | Output current | | | | T _A = -55°C to 125°C | -10 | | | mA |
| | | V _S = 15 V; V _O = 15 V; V _{ID} = -1 Sink | | | | 10 | 20 | | |
| | | | | $T_A = -55^{\circ}\text{C to } 125^{\circ}$ | | 5 | | | |
| | $V_{ID} = -1 \text{ V; } V_{O} = 200 \text{ mV}$ | | | | | 12 | 30 | | μA |
| sc | Short-circuit current | $V_S = 10 \text{ V}; V_O = V_S / 2$ | | | | | ±40 | ±60 | mA |

Instruments

5.9 Electrical Characteristics: LM158, LM158A (continued)

| | PARAMETER | MIN | TYP ⁽²⁾ | MAX | UNIT | | |
|-----|-----------------------------------|--|---------------------------------|-----|------|------|----|
| P | OWER SUPPLY | | | | | | |
| Ī. | Outleasant account non annulifian | V _O = 2.5 V; I _O = 0 A | T _A = -55°C to 125°C | | 350 | 600 | μA |
| Į'a | | V _S = 30 V; V _O = 15 V; I _O = 0 A | 1A33 C to 125 C | | 500 | 1000 | μΑ |

- All characteristics are measured under open-loop conditions, with zero common-mode input voltage, unless otherwise specified. Maximum V_S for testing purposes is 30 V for LM158 and LM158A.
- (2) All typical values are $T_A = 25$ °C.
- (3) On products compliant to MIL-PRF-38535, this parameter is not production tested.

5.10 Electrical Characteristics: LM258, LM258A

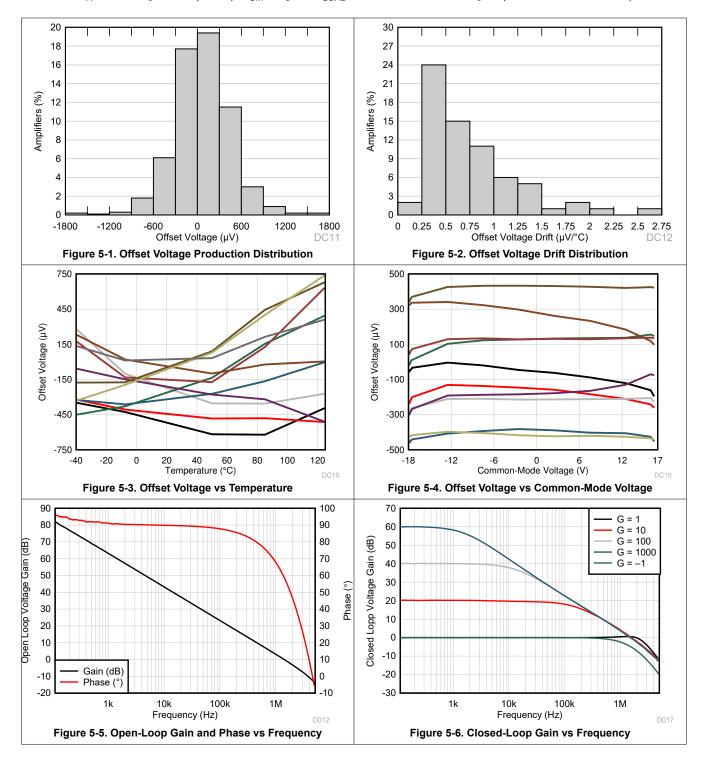
| | PARAMETER | TE | ST CONDI | TIONS ⁽¹⁾ | | MIN | TYP ⁽²⁾ | MAX | UNIT |
|----------------------------------|--|--|-----------------------|---------------------------|--|------|--------------------|------------|--------------------|
| OFFSET | VOLTAGE | | | | | | | | |
| | | | | LMOEG | | | 3 | 5 | |
| , | | | 4.437 | LM258 | T _A = -25°C to 85°C | | | 7 | ., |
| Vos | Input offset voltage | $V_S = 5 \text{ V to } 30 \text{ V; } V_{C \text{ M}} = 0 \text{ V; } V_{C}$ | _D = 1.4 V | | | | 2 | 3 | mV |
| | | | | LM258A | T _A = -25°C to 85°C | | | 4 | |
| | | | | LM258 | | | 7 | | |
| dV _{OS} /d _T | Input offset voltage drift | | | LM258A | $T_A = -25^{\circ}\text{C to } 85^{\circ}\text{C}$ | | 7 | 15 | μV/°C |
| PSRR | Input offset voltage vs power supply | V _S = 5 V to 30 V | | I | | 65 | 100 | | dB |
| Vos/ Vos | $(\Delta V_{IO}/\Delta V_S)$ Channel separation | f = 1 kHz to 20 kHz | | | | | 120 | | dB |
| | OLTAGE RANGE | T INTE TO ZO RITE | | | | | 120 | | ub |
| | OLIAGE MANGE | V _S = 5 V to 30 V | | LM258 | | | | | |
| | | V _S = 30 V | | LM258A | | (V-) | | (V+) – 1.5 | |
| V _{CM} | Common-mode voltage range | V _S = 5 V to 30 V | | LM258 | | | | | V |
| | | | | LM258A | − T _A = −25°C to 85°C | (V-) | | (V+) – 2 | |
| CMDD | Common woods unication natio | V _S = 30 V | | LM258A | | 70 | 90 | | 40 |
| CMRR | Common-mode rejection ratio | V _S = 5 V to 30 V; V _{CM} = 0 V | | | | 70 | 80 | | dB |
| INPULB | IAS CURRENT | | | 1 | | | | .=- | |
| | | | | LM258 | | | -20 | -150 | |
| I _B | Input bias current | V _O = 1.4 V | | | T _A = -25°C to 85°C | | | -300 | nA |
| | | | | LM258A | | | -15 | -80 | |
| | | | | | T _A = -25°C to 85°C | | | -100 | |
| | | | | LM258 | | | 2 | 30 | |
| I _{os} | Input offset current | V _O = 1.4 V | | | T _A = -25°C to 85°C | | | 100 | nA |
| | · | | | LM258A | | , | 2 | 15 | |
| | | | | | T _A = -25°C to 85°C | | | 30 | |
| dl _{OS} /d _T | Input offset current drift | | | | | | 10 | | pA/°C |
| ui0S/u | input onset current and | | | LM258A | T _A = -25°C to 85°C | | | 200 | pA 0 |
| NOISE | | | | | | | | | |
| e _n | Input voltage noise density | f = 1 kHz | | | | | 40 | | nV/√ Hz |
| OPEN-LO | OOP GAIN | | | | | | | | |
| ٨ | Open leen voltage gein | \/ = 15\/:\/ = 1\/:to 11\/:D | > 2 1/0 | | | 50 | 100 | | V/mV |
| A _{OL} | Open-loop voltage gain | $V_S = 15 \text{ V}; V_O = 1 \text{ V to } 11 \text{ V}; R_L$ | ≥ 2 KΩ | | T _A = -25°C to 85°C | 25 | | | V/IIIV |
| FREQUE | NCY RESPONSE | | | | | | | | |
| GBW | Gain bandwidth product | | | | | | 0.7 | | MHz |
| SR | Slew rate | G = +1 | | | | | 0.3 | | V/µs |
| OUTPUT | | | | | L | | | | |
| | | | V _S = 30 V | '; R _L = 2 kΩ | T _A = -25°C to 85°C | | | 4 | |
| | | Positive rail | | '; R _L ≥ 10 kΩ | | | 2 | 3 | V |
| V _O | Voltage output swing from rail | | | R _L ≥ 2 kΩ | | , | | 1.5 | |
| | | Negative rail | | R _L ≤ 10 kΩ | T _A = -25°C to 85°C | | 5 | 20 | mV |
| | | 13 | 13 7 1, | | - A | -20 | -30 | | |
| | | V _S = 15 V; V _O = 0 V; V _{ID} = 1 V | Source | LM258A | | | | -60 | |
| | | | | LIVIZOOA | T _A = -25°C to 85°C | -10 | | -00 | mΛ |
| l _o | Output current | | | | 1A20 0 10 00 0 | 10 | 20 | | mA |
| | | V _S = 15 V; V _O = 15 V; V _{ID} = -1 Sink | | | T = 05°C + 05°C | | 20 | | |
| | | · · · · · · · · · · · · · · · · · · · | | | T _A = -25°C to 85°C | 5 | 20 | | , . A |
| | Observation of the second seco | V _{ID} = -1 V; V _O = 200 mV | 12 | 30 | . 0.5 | μA | | | |
| I _{SC} | Short-circuit current | V _S = 10 V; V _O = V _S / 2 | | | | | ±40 | ±60 | mA |
| POWER | SUPPLY | I | | | | | | | |
| Iq | Quiescent current per amplifier | V _O = 2.5 V; I _O = 0 A | | | T _A = -25°C to 85°C | , | 350 | 600 | μA |
| | | $V_S = 30 \text{ V}; V_O = 15 \text{ V}; I_O = 0 \text{ A}$ | | | 1 22 | | 500 | 1000 | |

⁽¹⁾ All characteristics are measured under open-loop conditions, with zero common-mode input voltage, unless otherwise specified. Maximum V_S for testing purposes is 30 V for LM258 and LM258A.

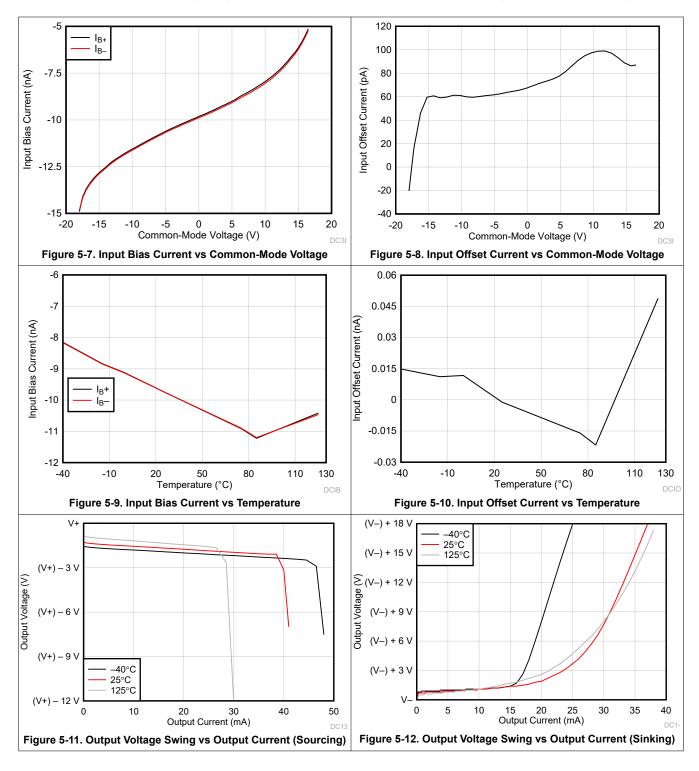
⁽²⁾ All typical values are T_A = 25°C.



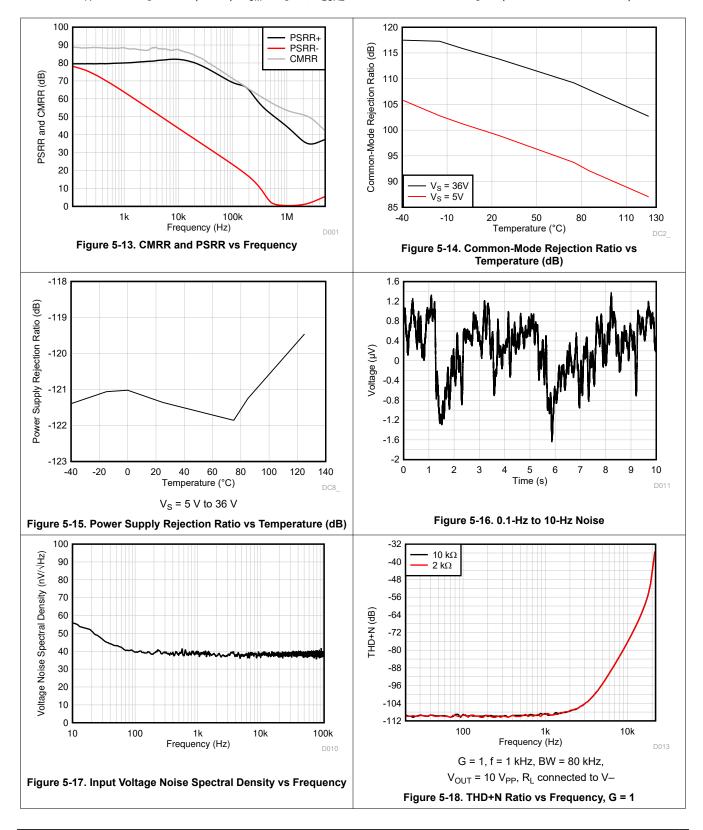
5.11 Typical Characteristics: LM358B and LM2904B

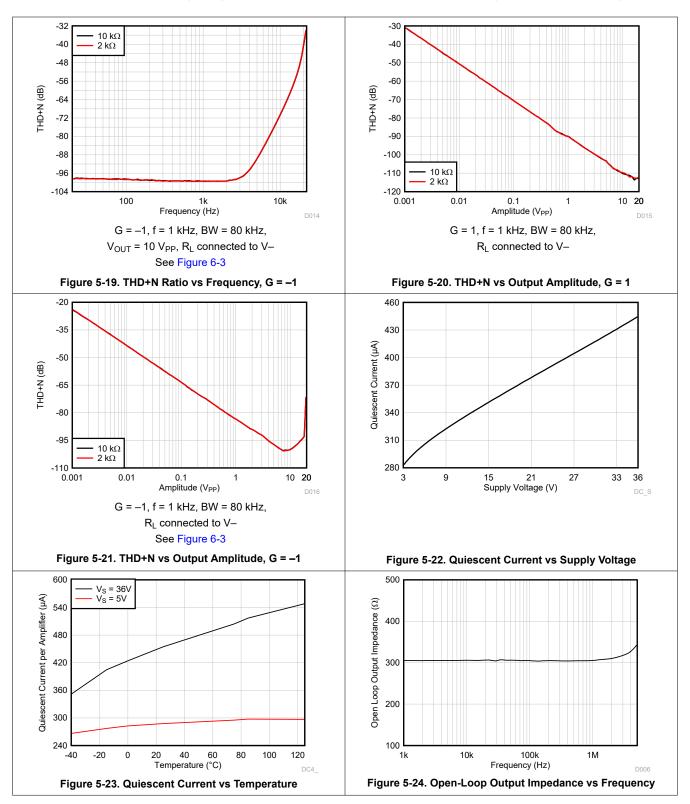




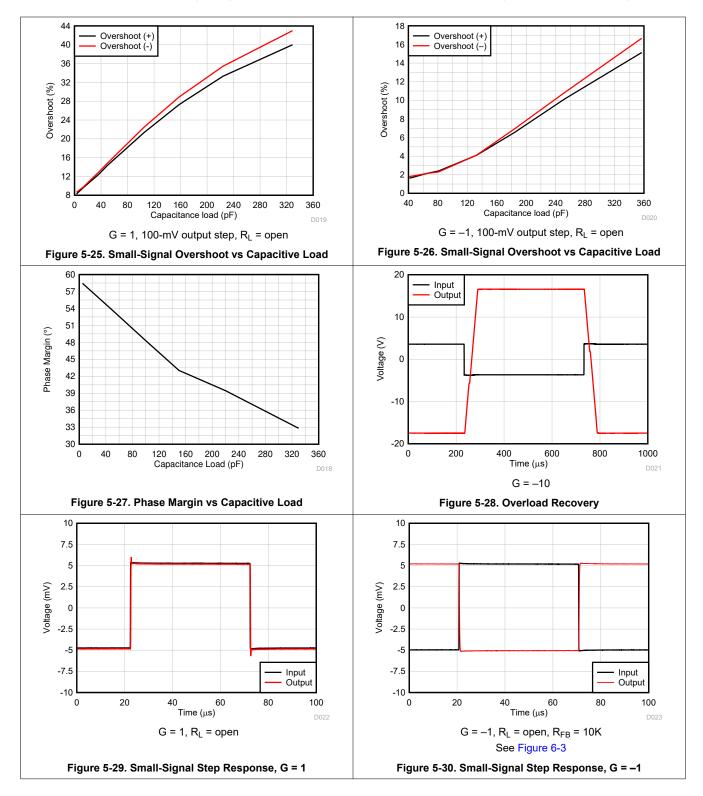




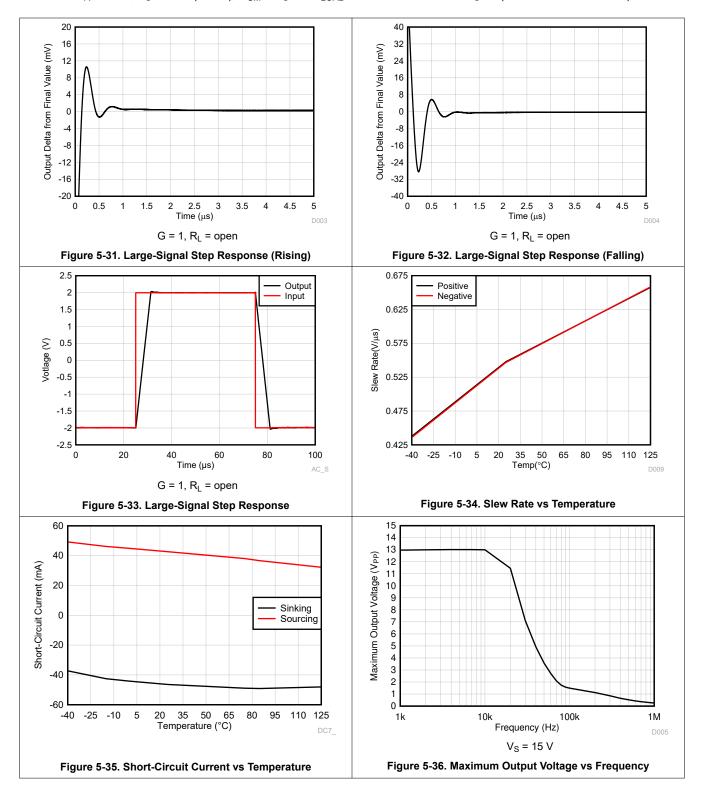




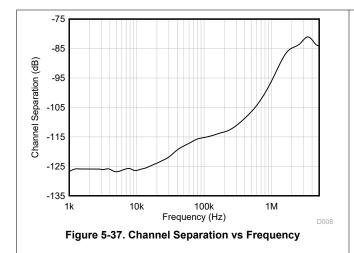












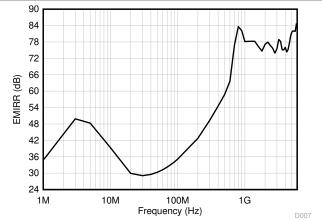
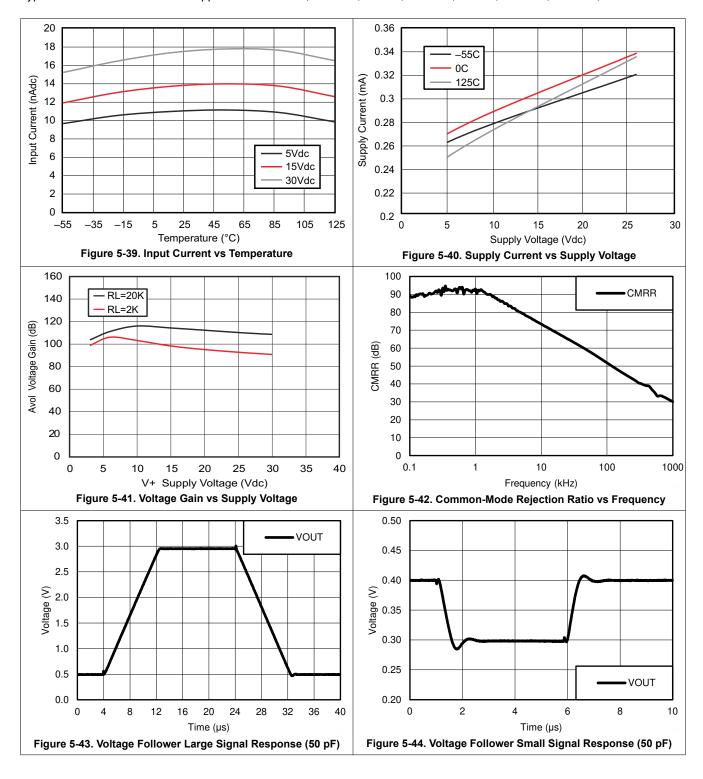


Figure 5-38. EMIRR (Electromagnetic Interference Rejection Ratio) vs Frequency



5.12 Typical Characteristics: LM158, LM158A, LM258, LM258A, LM358A, LM2904, and LM2904V

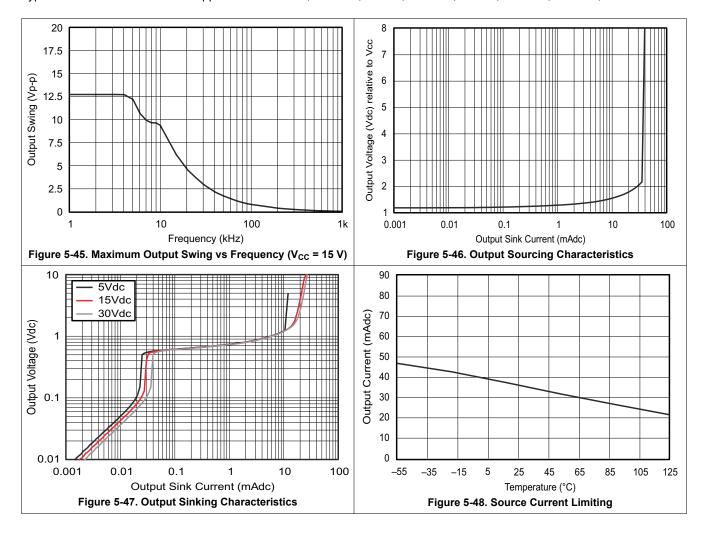
Typical characteristics section is applicable for LM158, LM158A, LM258, LM258A, LM358A, LM358A, LM2904, and LM2904V.





5.12 Typical Characteristics: LM158, LM158A, LM258, LM258A, LM358, LM358A, LM2904, and LM2904V (continued)

Typical characteristics section is applicable for LM158, LM158A, LM258, LM258A, LM358A, LM358A, LM2904, and LM2904V.





6 Parameter Measurement Information

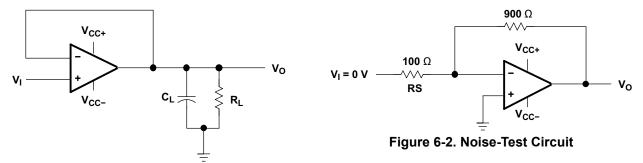


Figure 6-1. Unity-Gain Amplifier

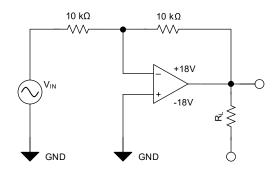


Figure 6-3. Test Circuit, G = -1, for THD+N and Small-Signal Step Response



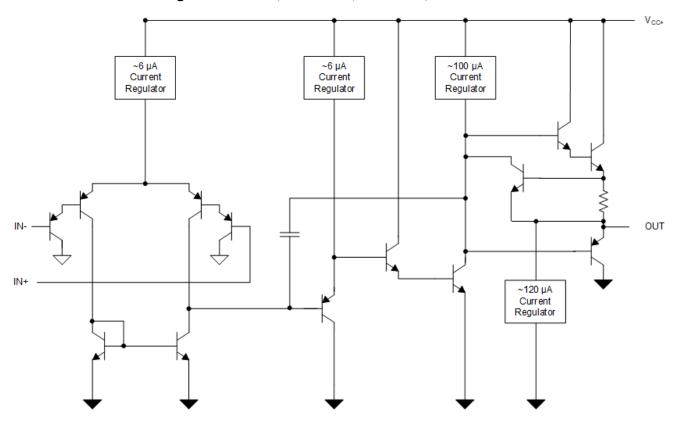
7 Detailed Description

7.1 Overview

These devices consist of two independent, high-gain frequency-compensated operational amplifiers designed to operate from a single supply over a wide range of voltages. Operation from split supplies also is possible if the difference between the two supplies is within the supply voltage range specified in Recommended Operating Conditions and V_S is at least 1.5 V more positive than the input common-mode voltage. The low supply-current drain is independent of the magnitude of the supply voltage.

Applications include transducer amplifiers, dc amplification blocks, and all the conventional operational amplifier circuits that now can be implemented more easily in single-supply-voltage systems. For example, these devices can be operated directly from the standard 5-V supply used in digital systems and easily can provide the required interface electronics without additional ±5-V supplies.

7.2 Functional Block Diagram: LM358B, LM358BA, LM2904B, LM2904BA





7.3 Feature Description

7.3.1 Unity-Gain Bandwidth

The unity-gain bandwidth is the frequency up to which an amplifier with a unity gain may be operated without greatly distorting the signal. These devices have a 1.2-MHz unity-gain bandwidth (B Version).

7.3.2 Slew Rate

The slew rate is the rate at which an operational amplifier can change its output when there is a change on the input. These devices have a 0.5-V/µs slew rate (B Version).

7.3.3 Input Common-Mode Range

The valid common-mode range is from device ground to $V_S - 1.5 \text{ V}$ ($V_S - 2 \text{ V}$ across temperature). Inputs may exceed V_S up to the maximum V_S without device damage. At least one input must be in the valid input common-mode range for the output to be the correct phase. If both inputs exceed the valid range, then the output phase is undefined. If either input more than 0.3 V below V– then input current should be limited to 1 mA and the output phase is undefined.

7.4 Device Functional Modes

These devices are powered on when the supply is connected. This device can be operated as a single-supply operational amplifier or dual-supply amplifier, depending on the application.

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The LMx58 and LM2904 operational amplifiers are useful in a wide range of signal conditioning applications. Inputs can be powered before V_Sfor flexibility in multiple supply circuits.

8.2 Typical Application

A typical application for an operational amplifier is an inverting amplifier. This amplifier takes a positive voltage on the input, and makes it a negative voltage of the same magnitude. In the same manner, it also makes negative voltages positive.

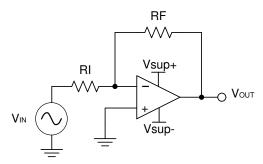


Figure 8-1. Application Schematic

8.2.1 Design Requirements

The supply voltage must be chosen such that it is larger than the input voltage range and output range. For instance, this application scales a signal of ± 0.5 V to ± 1.8 V. Setting the supply at ± 12 V is sufficient to accommodate this application.

8.2.2 Detailed Design Procedure

Determine the gain required by the inverting amplifier using Equation 1 and Equation 2:

$$A_{V} = \frac{VOUT}{VIN}$$
 (1)

$$A_{V} = \frac{1.8}{-0.5} = -3.6 \tag{2}$$

Once the desired gain is determined, choose a value for R_I or R_F . [Subscripts should be fixed in the accompanying figures and equations also.] Choosing a value in the kilohm range is desirable because the amplifier circuit uses currents in the milliampere range. This ensures the part does not draw too much current. This example uses 10 k Ω for R_I which means 36 k Ω is used for R_F . This was determined by Equation 3.

$$A_{V} = -\frac{RF}{RI}$$
 (3)



8.2.3 Application Curve

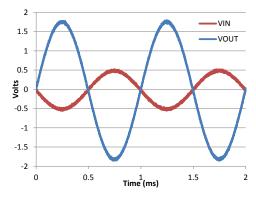


Figure 8-2. Input and Output Voltages of the Inverting Amplifier

8.3 Power Supply Recommendations

CAUTION

Supply voltages larger than specified in the recommended operating region can permanently damage the device (see *Absolute Maximum Ratings*).

Place 0.1-µF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, see Section 8.4.

8.4 Layout

8.4.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole, as well as the
 operational amplifier. Bypass capacitors are used to reduce the coupled noise by providing low-impedance
 power sources local to the analog circuitry.
 - Connect low-ESR, 0.1-µF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for singlesupply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically separate digital and analog grounds, paying attention to the flow of the ground current.
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If it is not possible to keep them separate, it is much better to cross the sensitive trace perpendicular as opposed to in parallel with the noisy trace.
- Place the external components as close to the device as possible. Keeping R_F and R_G close to the inverting
 input minimizes parasitic capacitance, as shown in *Layout Examples*.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.

8.4.2 Layout Examples

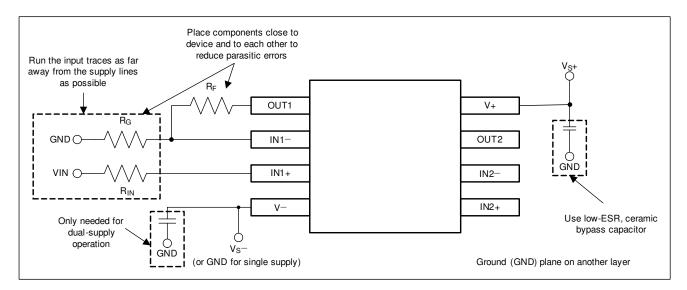


Figure 8-3. Operational Amplifier Board Layout for Noninverting Configuration

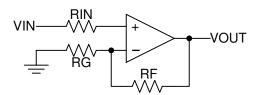


Figure 8-4. Operational Amplifier Schematic for Noninverting Configuration



9 Device and Documentation Support

9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.3 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

9.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Changes from Revision AA (March 2022) to Revision AB (October 2024) | Page |
|---|----------------|
| Changed Device Information table to Package Information Changed the polarity of the LM358B and LM358BA input bias current value from ± to – in the Elect | |
| Characteristics section | |
| • Changed the polarity of the LM2904B and LM2904BA input bias current value from ± to – in the Ele | |
| Characteristics section | 88 |
| | |
| Changes from Revision Z (July 2021) to Revision AA (March 2022) | Page |
| Added LM358BA and LM2904BA to the Device Information table | |
| Added Family Comparison table to the Description section | |
| • Raised ESD (CDM) for B-versions and BA-versions from 1 kV to 1.5 kV in the ESD Ratings table | |
| • Changed Input Offset Voltage Max of LM2904BA from T _A = -40°C to +125°C from ±2.5 mV to ±3.0 | mV8 |
| Changes from Revision Y (February 2021) to Revision Z (July 2021) | Page |
| • Deleted preview tag from LM358B and LM2904B SOT-23 (8) package in <i>Device Information</i> table. | 1 |
| Updated DDF (SOT-23) package thermal information in the <i>Thermal Information</i> table | <mark>5</mark> |
| Deleted Related Links from the Device and Documentation Support section | 30 |



www.ti.com

| C | hanges from Revision X (June 2020) to Revision Y (February 2021) | Page |
|----------|---|------|
| • | Updated the numbering format for tables, figures, and cross-references throughout the document | 1 |
| • | Added SOT23-8 (DDF) package information throughout data sheet | 1 |
| • | Deleted preview tag from LM358B and LM2904B VSSOP (8) package in Device Information table | 1 |
| • | Added SOT23-8 (DDF) package information to the Pin Configuration and Functions section | 3 |
| • | Added DDF (SOT-23) package to the <i>Thermal Information</i> table | 5 |
| _ | | |
| С | hanges from Revision W (October 2019) to Revision X (June 2020) | Page |
| • | Added application links to Applications section | 1 |
| • | Deleted preview tag from LM358B and LM2904B TSSOP (8) package in <i>Device Information</i> table | 1 |
| | | |
| С | hanges from Revision V (September 2018) to Revision W (October 2019) | |
| • | Changed CDM ESD rating for LM358B and LM2904B in ESD Ratings | |
| • | Changed V _S to V+ in Recommended Operating Conditions | |
| • | Changed Thermal Information for the LM158FK and LM158JG devices | |
| • | Added Typical Characteristics section for the LM358B and LM2490B op amps | 15 |
| • | Added test circuit for THD+N and small-signal step response, G = -1 in the <i>Parameter Measurement</i> | 0.4 |
| | Information section | |
| • | Changed the Functional Block Diagram | 25 |
| <u>c</u> | hanges from Revision U (January 2017) to Revision V (September 2018) Changed the data sheet title | |
| | Changed first four items in the <i>Features</i> section | |
| • | Changed the first item in the <i>Applications</i> section and added four new items | |
| | Changed voltage values in the first paragraph of the <i>Description</i> section | |
| | Changed text in the second paragraph of the <i>Description</i> section | |
| | Added devices LM358B and LM2904B to data sheet | |
| • | Changed the first three rows of the <i>Device Information</i> table and added a cross-referenced note for | |
| | PREVIEW-status devices | 1 |
| • | Added a table note to the <i>Pin Functions</i> table | |
| • | Changed "free-air temperature" to "ambient temperature" in the Absolute Maximum Ratings | |
| | condition statement | |
| • | Changed all entries in the Absolute Maximum Ratings table except T _J and T _{stg} | 4 |
| • | Deleted lead temperature and case temperature from Absolute Maximum Ratings | |
| • | Changed device listings and their voltage values in the ESD Ratings table | 4 |
| • | Changed "free-air temperature" to "ambient temperature" in the Recommended Operating Conditions | _ |
| | condition statement | |
| • | Changed table entries for all parameters in the Recommended Operating Conditions table | |
| • | Added rows to the Thermal Information table, and a table note regarding device-package combinations | |
| • | Deleted the Operating Conditions table | |
| • | Added a condition statement to the <i>Typical Characteristics</i> section | |
| • | Changed specific voltages to a Recommended Operating Conditions reference | |
| • | Changed unity-gain bandwidth from 0.7 MHz for all devices to 1.2 MHz for B-version devices | |
| • | Changed slew rate from 3 V/µs for all devices to 0.5 V/µs for B-version devices | |
| • | Changed the Input Common-Mode Range section in multiple places throughout | |
| • | Changed V _{CC} to V _S in the <i>Application Information</i> section | |
| • | OUDDOING UIF DUING IIV N AIN NE | ∠ / |



| Changed Operational Amplifier Board Layout for Noninverting Configuration with an image the dual op amp | |
|---|----------------------|
| Changes from Revision T (April 2015) to Revision U (January 2017) | Page |
| Changed data sheet title | 1 |
| Changes from Revision S (January 2014) to Revision T (April 2015) | Page |
| Added Applications section, ESD Ratings table, Feature Description section, Device Function Application and Implementation section, Power Supply Recommendations section, Layout se and Documentation Support section, and Mechanical, Packaging, and Orderable Information | ction, <i>Device</i> |
| Changes from Revision R (July 2010) to Revision S (January 2014) | Page |
| Converted this data sheet from the QS format to DocZone using the PDF on the web Deleted Ordering Information table | 1 |
| Updated Features to include Military Disclaimer. Added Typical Characteristics section. | 1 22 |

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most-current data available for the designated devices. This data is subject to change without notice and without revision of this document. For browser based versions of this data sheet, see the left-hand navigation pane.

www.ti.com 7-May-2025

PACKAGING INFORMATION

| Orderable part number | Status (1) | Material type | Package Pins | Package qty Carrier | RoHS | Lead finish/ Ball material | MSL rating/ Peak reflow | Op temp (°C) | Part marking (6) |
|--------------------------|------------|---------------|-----------------|-----------------------|------|-------------------------------|----------------------------|--------------|---------------------------------|
| 5962-87710012A | Active | Production | LCCC (FK) 20 | 55 TUBE | No | SNPB | N/A for Pkg Type | -55 to 125 | 5962- 87710012A LM158FKB |
| 5962-8771001PA | Active | Production | CDIP (JG) 8 | 50 TUBE | No | SNPB | N/A for Pkg Type | -55 to 125 | 8771001PA LM158 |
| 5962-87710022A | Active | Production | LCCC (FK) 20 | 55 TUBE | No | SNPB | N/A for Pkg Type | -55 to 125 | 5962- 87710022A LM158AFKB |
| 5962-8771002PA | Active | Production | CDIP (JG) 8 | 50 TUBE | No | SNPB | N/A for Pkg Type | -55 to 125 | 8771002PA LM158A |
| LM158AFKB | Active | Production | LCCC (FK) 20 | 55 TUBE | No | SNPB | N/A for Pkg Type | -55 to 125 | 5962- 87710022A LM158AFKB |
| LM158AJG | Active | Production | CDIP (JG) 8 | 50 TUBE | No | SNPB | N/A for Pkg Type | -55 to 125 | LM158AJG |
| LM158AJGB | Active | Production | CDIP (JG) 8 | 50 TUBE | No | SNPB | N/A for Pkg Type | -55 to 125 | 8771002PA LM158A |
| LM158FKB | Active | Production | LCCC (FK) 20 | 55 TUBE | No | SNPB | N/A for Pkg Type | -55 to 125 | 5962- 87710012A LM158FKB |
| LM158JG | Active | Production | CDIP (JG) 8 | 50 TUBE | No | SNPB | N/A for Pkg Type | -55 to 125 | LM158JG |
| LM158JGB | Active | Production | CDIP (JG) 8 | 50 TUBE | No | SNPB | N/A for Pkg Type | -55 to 125 | 8771001PA LM158 |
| LM258ADGKR | Active | Production | VSSOP (DGK) 8 | 2500 LARGE T&R | Yes | NIPDAU SN NIPDAU | Level-1-260C-UNLIM | -25 to 85 | (M3L, M3P, M3S, M3 U) |
| LM258ADR | Active | Production | SOIC (D) 8 | 2500 LARGE T&R | Yes | NIPDAU SN | Level-1-260C-UNLIM | -25 to 85 | LM258A |
| LM258ADRG4 | Active | Production | SOIC (D) 8 | 2500 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -25 to 85 | LM258A |
| LM258AP | Active | Production | PDIP (P) 8 | 50 TUBE | Yes | NIPDAU | N/A for Pkg Type | -25 to 85 | LM258AP |
| LM258APE4 | Active | Production | PDIP (P) 8 | 50 TUBE | Yes | NIPDAU | N/A for Pkg Type | -25 to 85 | LM258AP |
| LM258DGKR | Active | Production | VSSOP (DGK) 8 | 2500 LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -25 to 85 | (M2L, M2P, M2S, M2 U) |
| LM258DR | Active | Production | SOIC (D) 8 | 2500 LARGE T&R | Yes | NIPDAU SN | Level-1-260C-UNLIM | -25 to 85 | LM258 |
| LM258DRG3 | Obsolete | Production | SOIC (D) 8 | - | - | Call TI | Call TI | -25 to 85 | LM258 |
| LM258DRG4 | Active | Production | SOIC (D) 8 | 2500 LARGE T&R | Yes | NIPDAU NIPDAU | Level-1-260C-UNLIM | -25 to 85 | LM258 |





www.ti.com 7-May-2025

| Orderable part number | Status | Material type | Package Pins | Package qty Carrier | RoHS (3) | Lead finish/ Ball material | MSL rating/ Peak reflow | Op temp (°C) | Part marking (6) |
|--------------------------|----------|---------------|-----------------------|-----------------------|----------|-------------------------------|----------------------------|--------------|--------------------------|
| LM258P | Active | Production | PDIP (P) 8 | 50 TUBE | Yes | NIPDAU SN | N/A for Pkg Type | -25 to 85 | LM258P |
| LM258PE4 | Active | Production | PDIP (P) 8 | 50 TUBE | Yes | NIPDAU | N/A for Pkg Type | -25 to 85 | LM258P |
| LM2904AVQDR | Active | Production | SOIC (D) 8 | 2500 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | L2904AV |
| LM2904AVQDRG4 | Active | Production | SOIC (D) 8 | 2500 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | L2904AV |
| LM2904AVQPWR | Active | Production | TSSOP (PW) 8 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | L2904AV |
| LM2904AVQPWRG4 | Active | Production | TSSOP (PW) 8 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | L2904AV |
| LM2904BAIDDFR | Active | Production | SOT-23-THIN (DDF) 8 | 3000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | 2904A |
| LM2904BAIDGKR | Active | Production | VSSOP (DGK) 8 | 2500 LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 28CB |
| LM2904BAIDR | Active | Production | SOIC (D) 8 | 2500 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | 2904BA |
| LM2904BAIPWR | Active | Production | TSSOP (PW) 8 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | 2904BA |
| LM2904BIDDFR | Active | Production | SOT-23-THIN (DDF) 8 | 3000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | L2904 |
| LM2904BIDGKR | Active | Production | VSSOP (DGK) 8 | 2500 LARGE T&R | Yes | NIPDAU SN | Level-1-260C-UNLIM | -40 to 125 | 28BB |
| LM2904BIDR | Active | Production | SOIC (D) 8 | 2500 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | L2904B |
| LM2904BIPWR | Active | Production | TSSOP (PW) 8 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | L2904B |
| LM2904DE4 | NRND | Production | null (null) | 75 TUBE | - | Call TI | Call TI | -40 to 125 | |
| LM2904DGKR | Active | Production | VSSOP (DGK) 8 | 2500 LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | (MBL, MBP, MBS, MB U) |
| LM2904DR | Active | Production | SOIC (D) 8 | 2500 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | LM2904 |
| LM2904DRG3 | Obsolete | Production | SOIC (D) 8 | - | - | Call TI | Call TI | -40 to 125 | LM2904 |
| LM2904DRG4 | Obsolete | Production | SOIC (D) 8 | - | - | Call TI | Call TI | -40 to 125 | LM2904 |
| LM2904P | Active | Production | PDIP (P) 8 | 50 TUBE | Yes | NIPDAU | N/A for Pkg Type | -40 to 125 | LM2904P |
| LM2904PE4 | Active | Production | PDIP (P) 8 | 50 TUBE | Yes | NIPDAU | N/A for Pkg Type | -40 to 125 | LM2904P |
| LM2904PSR | Active | Production | SO (PS) 8 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | L2904 |
| LM2904PWR | Active | Production | TSSOP (PW) 8 | 2000 LARGE T&R | Yes | NIPDAU SN | Level-1-260C-UNLIM | -40 to 125 | L2904 |
| LM2904PWRG3 | Obsolete | Production | TSSOP (PW) 8 | - | - | Call TI | Call TI | -40 to 125 | L2904 |
| LM2904PWRG4-JF | Obsolete | Production | TSSOP (PW) 8 | - | - | Call TI | Call TI | -40 to 125 | L2904 |
| LM2904QDR | Active | Production | SOIC (D) 8 | 2500 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | 2904Q1 |
| LM2904QDRG4 | Obsolete | Production | SOIC (D) 8 | - | - | Call TI | Call TI | -40 to 125 | 2904Q1 |
| LM2904VQDR | Active | Production | SOIC (D) 8 | 2500 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | L2904V |
| LM2904VQDRG4 | Active | Production | SOIC (D) 8 | 2500 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | L2904V |
| LM2904VQPWR | Active | Production | TSSOP (PW) 8 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | L2904V |





www.ti.com

7-May-2025

| Orderable part number | Status (1) | Material type | Package Pins | Package qty Carrier | RoHS | Lead finish/ Ball material | MSL rating/ Peak reflow | Op temp (°C) | Part marking (6) |
|-----------------------|------------|---------------|-----------------------|-----------------------|------|-------------------------------|----------------------------|--------------|--------------------------|
| LM2904VQPWRG4 | Active | Production | TSSOP (PW) 8 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | L2904V |
| LM358ADE4 | NRND | Production | null (null) | 75 TUBE | - | Call TI | Call TI | 0 to 70 | |
| LM358ADGKR | Active | Production | VSSOP (DGK) 8 | 2500 LARGE T&R | Yes | SN | Level-1-260C-UNLIM | 0 to 70 | (M6L, M6P, M6S, M6 U) |
| LM358ADR | Active | Production | SOIC (D) 8 | 2500 LARGE T&R | Yes | NIPDAU SN | Level-1-260C-UNLIM | 0 to 70 | LM358A |
| LM358ADRG4 | Obsolete | Production | SOIC (D) 8 | - | - | Call TI | Call TI | 0 to 70 | LM358A |
| LM358AP | Active | Production | PDIP (P) 8 | 50 TUBE | Yes | NIPDAU | N/A for Pkg Type | 0 to 70 | LM358AP |
| LM358APE4 | Active | Production | PDIP (P) 8 | 50 TUBE | Yes | NIPDAU | N/A for Pkg Type | 0 to 70 | LM358AP |
| LM358APW | Obsolete | Production | TSSOP (PW) 8 | - | - | Call TI | Call TI | 0 to 70 | L358A |
| LM358APWR | Active | Production | TSSOP (PW) 8 | 2000 LARGE T&R | Yes | NIPDAU SN | Level-1-260C-UNLIM | 0 to 70 | L358A |
| LM358BAIDDFR | Active | Production | SOT-23-THIN (DDF) 8 | 3000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | 358BA |
| LM358BAIDGKR | Active | Production | VSSOP (DGK) 8 | 2500 LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 85 | 28DB |
| LM358BAIDR | Active | Production | SOIC (D) 8 | 2500 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | L358BA |
| LM358BAIPWR | Active | Production | TSSOP (PW) 8 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | L358BA |
| LM358BIDDFR | Active | Production | SOT-23-THIN (DDF) 8 | 3000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LM358 |
| LM358BIDGKR | Active | Production | VSSOP (DGK) 8 | 2500 LARGE T&R | Yes | NIPDAU SN | Level-1-260C-UNLIM | -40 to 85 | (1TKR, 358B) |
| LM358BIDR | Active | Production | SOIC (D) 8 | 2500 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LM358B |
| LM358BIPWR | Active | Production | TSSOP (PW) 8 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | LM358B |
| LM358D | Obsolete | Production | SOIC (D) 8 | - | - | Call TI | Call TI | 0 to 70 | LM358 |
| LM358DGKR | Active | Production | VSSOP (DGK) 8 | 2500 LARGE T&R | Yes | SN | Level-1-260C-UNLIM | 0 to 70 | (M5L, M5P, M5S, M5 U) |
| LM358DR | Active | Production | SOIC (D) 8 | 2500 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | LM358 |
| LM358DRG3 | Obsolete | Production | SOIC (D) 8 | - | - | Call TI | Call TI | 0 to 70 | LM358 |
| LM358DRG4 | Obsolete | Production | SOIC (D) 8 | - | - | Call TI | Call TI | 0 to 70 | LM358 |
| LM358P | Active | Production | PDIP (P) 8 | 50 TUBE | Yes | NIPDAU | N/A for Pkg Type | 0 to 70 | LM358P |
| LM358PE3 | Obsolete | Production | PDIP (P) 8 | - | - | Call TI | Call TI | 0 to 70 | LM358P |
| LM358PE4 | Active | Production | PDIP (P) 8 | 50 TUBE | Yes | NIPDAU | N/A for Pkg Type | 0 to 70 | LM358P |
| LM358PSR | Active | Production | SO (PS) 8 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | L358 |
| LM358PW | Obsolete | Production | TSSOP (PW) 8 | - | - | Call TI | Call TI | 0 to 70 | L358 |
| LM358PWR | Active | Production | TSSOP (PW) 8 | 2000 LARGE T&R | Yes | NIPDAU SN | Level-1-260C-UNLIM | 0 to 70 | L358 |
| LM358PWRG3 | Obsolete | Production | TSSOP (PW) 8 | - | - | Call TI | Call TI | 0 to 70 | L358 |



www.ti.com 7-May-2025

| Orderable part number | Status (1) | Material type | Package Pins | Package qty Carrier | RoHS (3) | Lead finish/ Ball material | MSL rating/ Peak reflow | Op temp (°C) | Part marking (6) |
|-----------------------|---------------|---------------|----------------|-----------------------|-----------------|-------------------------------|----------------------------|--------------|------------------|
| LM358PWRG4 | Obsolete | Production | TSSOP (PW) 8 | - | - | Call TI | Call TI | 0 to 70 | L358 |
| LM358PWRG4-JF | Obsolete | Production | TSSOP (PW) 8 | - | - | Call TI | Call TI | 0 to 70 | L358 |

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF LM258A, LM2904, LM2904B, LM2904BA:

Automotive: LM2904-Q1, LM2904B-Q1, LM2904BA-Q1

■ Enhanced Product : LM258A-EP, LM2904-EP

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

www.ti.com 7-May-2025

NOTE: Qualified Version Definitions:

- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications



www.ti.com 3-May-2025

TAPE AND REEL INFORMATION





| | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|------------|-----------------|--------------------|------|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| LM258ADGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| LM258ADR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM258ADR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM258ADR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM258ADR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM258ADRG4 | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM258ADRG4 | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM258ADRG4 | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM258ADRG4 | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM258DGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.25 | 3.35 | 1.25 | 8.0 | 12.0 | Q1 |
| LM258DGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| LM258DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM258DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM258DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM258DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM258DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |



PACKAGE MATERIALS INFORMATION

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|-----------------|--------------------|------|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| LM258DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM258DRG4 | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM258DRG4 | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM258DRG4 | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM258DRG4 | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM2904AVQDR | SOIC | D | 8 | 2500 | 330.0 | 12.5 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM2904AVQDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM2904AVQDRG4 | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM2904AVQDRG4 | SOIC | D | 8 | 2500 | 330.0 | 12.5 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM2904AVQPWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LM2904AVQPWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LM2904AVQPWRG4 | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LM2904AVQPWRG4 | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LM2904BAIDDFR | SOT-23- THIN | DDF | 8 | 3000 | 180.0 | 8.4 | 3.2 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| LM2904BAIDGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.25 | 3.35 | 1.25 | 8.0 | 12.0 | Q1 |
| LM2904BAIDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM2904BAIDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM2904BAIDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM2904BAIDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM2904BAIPWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LM2904BAIPWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LM2904BIDDFR | SOT-23- THIN | DDF | 8 | 3000 | 180.0 | 8.4 | 3.2 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| LM2904BIDGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| LM2904BIDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM2904BIDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM2904BIDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM2904BIPWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LM2904BIPWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LM2904DGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| LM2904DGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.25 | 3.35 | 1.25 | 8.0 | 12.0 | Q1 |
| LM2904DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM2904DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM2904PSR | SO | PS | 8 | 2000 | 330.0 | 16.4 | 8.35 | 6.6 | 2.4 | 12.0 | 16.0 | Q1 |
| LM2904PWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LM2904PWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LM2904QDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM2904QDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM2904VQDR | SOIC | D | 8 | 2500 | 330.0 | 12.5 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM2904VQDRG4 | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM2904VQPWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |



PACKAGE MATERIALS INFORMATION

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|-----------------|--------------------|------|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| LM2904VQPWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LM2904VQPWRG4 | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LM2904VQPWRG4 | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LM358ADGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.25 | 3.35 | 1.25 | 8.0 | 12.0 | Q1 |
| LM358ADR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM358ADR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM358ADR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM358ADR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM358ADR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM358APWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LM358APWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LM358BAIDDFR | SOT-23- THIN | DDF | 8 | 3000 | 180.0 | 8.4 | 3.2 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| LM358BAIDGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.25 | 3.35 | 1.25 | 8.0 | 12.0 | Q1 |
| LM358BAIDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM358BAIDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM358BAIDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM358BAIDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM358BAIPWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LM358BAIPWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LM358BIDDFR | SOT-23- THIN | DDF | 8 | 3000 | 180.0 | 8.4 | 3.2 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| LM358BIDGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM358BIDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM358BIDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM358BIDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM358BIPWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LM358BIPWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LM358DGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| LM358DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM358DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM358PSR | so | PS | 8 | 2000 | 330.0 | 16.4 | 8.35 | 6.6 | 2.4 | 12.0 | 16.0 | Q1 |
| LM358PWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LM358PWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |





*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|------------|--------------|-----------------|------|------|-------------|------------|-------------|
| LM258ADGKR | VSSOP | DGK | 8 | 2500 | 356.0 | 356.0 | 35.0 |
| LM258ADR | SOIC | D | 8 | 2500 | 356.0 | 356.0 | 35.0 |
| LM258ADR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| LM258ADR | SOIC | D | 8 | 2500 | 340.5 | 336.1 | 25.0 |
| LM258ADR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| LM258ADRG4 | SOIC | D | 8 | 2500 | 356.0 | 356.0 | 35.0 |
| LM258ADRG4 | SOIC | D | 8 | 2500 | 356.0 | 356.0 | 35.0 |
| LM258ADRG4 | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| LM258ADRG4 | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| LM258DGKR | VSSOP | DGK | 8 | 2500 | 366.0 | 364.0 | 50.0 |
| LM258DGKR | VSSOP | DGK | 8 | 2500 | 356.0 | 356.0 | 35.0 |
| LM258DR | SOIC | D | 8 | 2500 | 356.0 | 356.0 | 35.0 |
| LM258DR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| LM258DR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| LM258DR | SOIC | D | 8 | 2500 | 356.0 | 356.0 | 35.0 |
| LM258DR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| LM258DR | SOIC | D | 8 | 2500 | 340.5 | 336.1 | 25.0 |
| LM258DRG4 | SOIC | D | 8 | 2500 | 356.0 | 356.0 | 35.0 |



PACKAGE MATERIALS INFORMATION

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| LM258DRG4 | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| LM258DRG4 | SOIC | D | 8 | 2500 | 356.0 | 356.0 | 35.0 |
| LM258DRG4 | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| LM2904AVQDR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| LM2904AVQDR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| LM2904AVQDRG4 | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| LM2904AVQDRG4 | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| LM2904AVQPWR | TSSOP | PW | 8 | 2000 | 356.0 | 356.0 | 35.0 |
| LM2904AVQPWR | TSSOP | PW | 8 | 2000 | 356.0 | 356.0 | 35.0 |
| LM2904AVQPWRG4 | TSSOP | PW | 8 | 2000 | 356.0 | 356.0 | 35.0 |
| LM2904AVQPWRG4 | TSSOP | PW | 8 | 2000 | 356.0 | 356.0 | 35.0 |
| LM2904BAIDDFR | SOT-23-THIN | DDF | 8 | 3000 | 210.0 | 185.0 | 35.0 |
| LM2904BAIDGKR | VSSOP | DGK | 8 | 2500 | 366.0 | 364.0 | 50.0 |
| LM2904BAIDR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| LM2904BAIDR | SOIC | D | 8 | 2500 | 356.0 | 356.0 | 35.0 |
| LM2904BAIDR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| LM2904BAIDR | SOIC | D | 8 | 2500 | 340.5 | 336.1 | 25.0 |
| LM2904BAIPWR | TSSOP | PW | 8 | 2000 | 356.0 | 356.0 | 35.0 |
| LM2904BAIPWR | TSSOP | PW | 8 | 2000 | 353.0 | 353.0 | 32.0 |
| LM2904BIDDFR | SOT-23-THIN | DDF | 8 | 3000 | 210.0 | 185.0 | 35.0 |
| LM2904BIDGKR | VSSOP | DGK | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| LM2904BIDR | SOIC | D | 8 | 2500 | 340.5 | 336.1 | 25.0 |
| LM2904BIDR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| LM2904BIDR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| LM2904BIPWR | TSSOP | PW | 8 | 2000 | 356.0 | 356.0 | 35.0 |
| LM2904BIPWR | TSSOP | PW | 8 | 2000 | 353.0 | 353.0 | 32.0 |
| LM2904DGKR | VSSOP | DGK | 8 | 2500 | 356.0 | 356.0 | 35.0 |
| LM2904DGKR | VSSOP | DGK | 8 | 2500 | 366.0 | 364.0 | 50.0 |
| LM2904DR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| LM2904DR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| LM2904PSR | SO | PS | 8 | 2000 | 356.0 | 356.0 | 35.0 |
| LM2904PWR | TSSOP | PW | 8 | 2000 | 353.0 | 353.0 | 32.0 |
| LM2904PWR | TSSOP | PW | 8 | 2000 | 356.0 | 356.0 | 35.0 |
| LM2904QDR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| LM2904QDR | SOIC | D | 8 | 2500 | 350.0 | 350.0 | 43.0 |
| LM2904VQDR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| LM2904VQDRG4 | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| LM2904VQPWR | TSSOP | PW | 8 | 2000 | 356.0 | 356.0 | 35.0 |
| LM2904VQPWR | TSSOP | PW | 8 | 2000 | 356.0 | 356.0 | 35.0 |
| LM2904VQPWRG4 | TSSOP | PW | 8 | 2000 | 356.0 | 356.0 | 35.0 |
| LM2904VQPWRG4 | TSSOP | PW | 8 | 2000 | 356.0 | 356.0 | 35.0 |
| LM358ADGKR | VSSOP | DGK | 8 | 2500 | 366.0 | 364.0 | 50.0 |
| LM358ADR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |

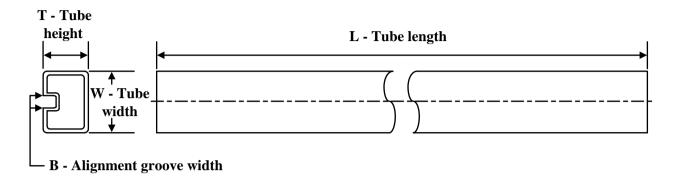


PACKAGE MATERIALS INFORMATION

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| LM358ADR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| LM358ADR | SOIC | D | 8 | 2500 | 356.0 | 356.0 | 35.0 |
| LM358ADR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| LM358ADR | SOIC | D | 8 | 2500 | 340.5 | 336.1 | 25.0 |
| LM358APWR | TSSOP | PW | 8 | 2000 | 353.0 | 353.0 | 32.0 |
| LM358APWR | TSSOP | PW | 8 | 2000 | 356.0 | 356.0 | 35.0 |
| LM358BAIDDFR | SOT-23-THIN | DDF | 8 | 3000 | 210.0 | 185.0 | 35.0 |
| LM358BAIDGKR | VSSOP | DGK | 8 | 2500 | 366.0 | 364.0 | 50.0 |
| LM358BAIDR | SOIC | D | 8 | 2500 | 340.5 | 336.1 | 25.0 |
| LM358BAIDR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| LM358BAIDR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| LM358BAIDR | SOIC | D | 8 | 2500 | 356.0 | 356.0 | 35.0 |
| LM358BAIPWR | TSSOP | PW | 8 | 2000 | 353.0 | 353.0 | 32.0 |
| LM358BAIPWR | TSSOP | PW | 8 | 2000 | 356.0 | 356.0 | 35.0 |
| LM358BIDDFR | SOT-23-THIN | DDF | 8 | 3000 | 210.0 | 185.0 | 35.0 |
| LM358BIDGKR | VSSOP | DGK | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| LM358BIDR | SOIC | D | 8 | 2500 | 340.5 | 336.1 | 25.0 |
| LM358BIDR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| LM358BIDR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| LM358BIPWR | TSSOP | PW | 8 | 2000 | 353.0 | 353.0 | 32.0 |
| LM358BIPWR | TSSOP | PW | 8 | 2000 | 356.0 | 356.0 | 35.0 |
| LM358DGKR | VSSOP | DGK | 8 | 2500 | 356.0 | 356.0 | 35.0 |
| LM358DR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| LM358DR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| LM358PSR | SO | PS | 8 | 2000 | 356.0 | 356.0 | 35.0 |
| LM358PWR | TSSOP | PW | 8 | 2000 | 356.0 | 356.0 | 35.0 |
| LM358PWR | TSSOP | PW | 8 | 2000 | 353.0 | 353.0 | 32.0 |

www.ti.com 3-May-2025

TUBE



*All dimensions are nominal

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (µm) | B (mm) |
|----------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| 5962-87710012A | FK | LCCC | 20 | 55 | 506.98 | 12.06 | 2030 | NA |
| 5962-87710022A | FK | LCCC | 20 | 55 | 506.98 | 12.06 | 2030 | NA |
| LM158AFKB | FK | LCCC | 20 | 55 | 506.98 | 12.06 | 2030 | NA |
| LM158FKB | FK | LCCC | 20 | 55 | 506.98 | 12.06 | 2030 | NA |
| LM258AP | Р | PDIP | 8 | 50 | 506 | 13.97 | 11230 | 4.32 |
| LM258APE4 | Р | PDIP | 8 | 50 | 506 | 13.97 | 11230 | 4.32 |
| LM258P | Р | PDIP | 8 | 50 | 506.1 | 9 | 600 | 5.4 |
| LM258P | Р | PDIP | 8 | 50 | 506 | 13.97 | 11230 | 4.32 |
| LM258PE4 | Р | PDIP | 8 | 50 | 506 | 13.97 | 11230 | 4.32 |
| LM2904P | Р | PDIP | 8 | 50 | 506 | 13.97 | 11230 | 4.32 |
| LM2904PE4 | Р | PDIP | 8 | 50 | 506 | 13.97 | 11230 | 4.32 |
| LM358AP | Р | PDIP | 8 | 50 | 506 | 13.97 | 11230 | 4.32 |
| LM358APE4 | Р | PDIP | 8 | 50 | 506 | 13.97 | 11230 | 4.32 |
| LM358P | Р | PDIP | 8 | 50 | 506 | 13.97 | 11230 | 4.32 |
| LM358PE4 | Р | PDIP | 8 | 50 | 506 | 13.97 | 11230 | 4.32 |

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



INSTRUMENTS www.ti.com



PLASTIC SMALL OUTLINE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.



PLASTIC SMALL OUTLINE



- 4. Publication IPC-7351 may have alternate designs.
- 5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PLASTIC SMALL OUTLINE



- 6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 7. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE INTEGRATED CIRCUIT



- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



PS (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153, variation AA.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



CERAMIC DUAL IN-LINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This package can be hermetically sealed with a ceramic lid using glass frit.

- 4. Index point is provided on cap for terminal identification. 5. Falls within MIL STD 1835 GDIP1-T8



CERAMIC DUAL IN-LINE PACKAGE







PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.





- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.





- 11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 12. Board assembly site may have different recommendations for stencil design.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2025. Texas Instruments Incorporated